

|                        |                                                                                                               |
|------------------------|---------------------------------------------------------------------------------------------------------------|
| <b>Title</b>           | <b><i>Reference Design Report for 14.5 W Standby and 300 W Main Power Supply Using HiperTFS™ TFS762HG</i></b> |
| <b>Specification</b>   | 300 VDC – 385 VDC Input; 5 V, 2.9 A (Standby) and 12 V, 25 A (Main) Outputs                                   |
| <b>Application</b>     | PC Power Supply                                                                                               |
| <b>Author</b>          | Applications Engineering Department                                                                           |
| <b>Document Number</b> | RDR-249                                                                                                       |
| <b>Date</b>            | November 16, 2011                                                                                             |
| <b>Revision</b>        | 1.1                                                                                                           |

#### **Summary and Features**

- High efficiency Main and Standby converters
- Remote on/off
- Built-in main and standby undervoltage thresholds protection ensures graceful power supply start-up and shutdown
- Latching output overvoltage protection
- Integrated high-side driver
- Output short-circuit and open loop protection
- Main transformer reset protection
- Flat standby overload versus input voltage

#### **PATENT INFORMATION**

The products and applications illustrated herein (including transformer construction and circuits external to the products) may be covered by one or more U.S. and foreign patents, or potentially by pending U.S. and foreign patent applications assigned to Power Integrations. A complete list of Power Integrations' patents may be found at [www.powerint.com](http://www.powerint.com). Power Integrations grants its customers a license under certain patent rights as set forth at <http://www.powerint.com/ip.htm>.

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**Important Note:**

Although this board is designed to satisfy safety isolation requirements, the engineering prototype has not been agency approved. Therefore, all testing should be performed using an AC isolation transformer to the DC power supply or power factor stage used to provide the input voltage.



## 1 Introduction

This document is an engineering report describing a 5 V, 2.9 A Standby and a 12 V, 25 A Main power supply utilizing the TFS762HG device from the HiperTFS family. This example power supply uses a fixed DC input voltage, but in a typical application, it would be connected to a PFC boost input stage, delivering approximately 385 VDC to implement a 300 W power supply with various output voltages. A lab bench DC power supply capable of 400 VDC at 3 A or an AC input rectifier stage is required supply to the input for evaluation. It is also possible to use the power factor circuit RDK-236 to provide the regulated 385 VDC needed to power RDK-249.

Typically PC power supplies have a universal AC input power factor corrected (PFC) input stage but as the bias standby supply must operate before the PFC stage is active, the Standby output must operate with the DC equivalent of universal AC input voltages (85 VAC to 265 VAC and 100 VDC to 400 VDC).

The document contains the power supply specification, schematic, bill of materials, transformer documentation, printed circuit layout, and performance data.

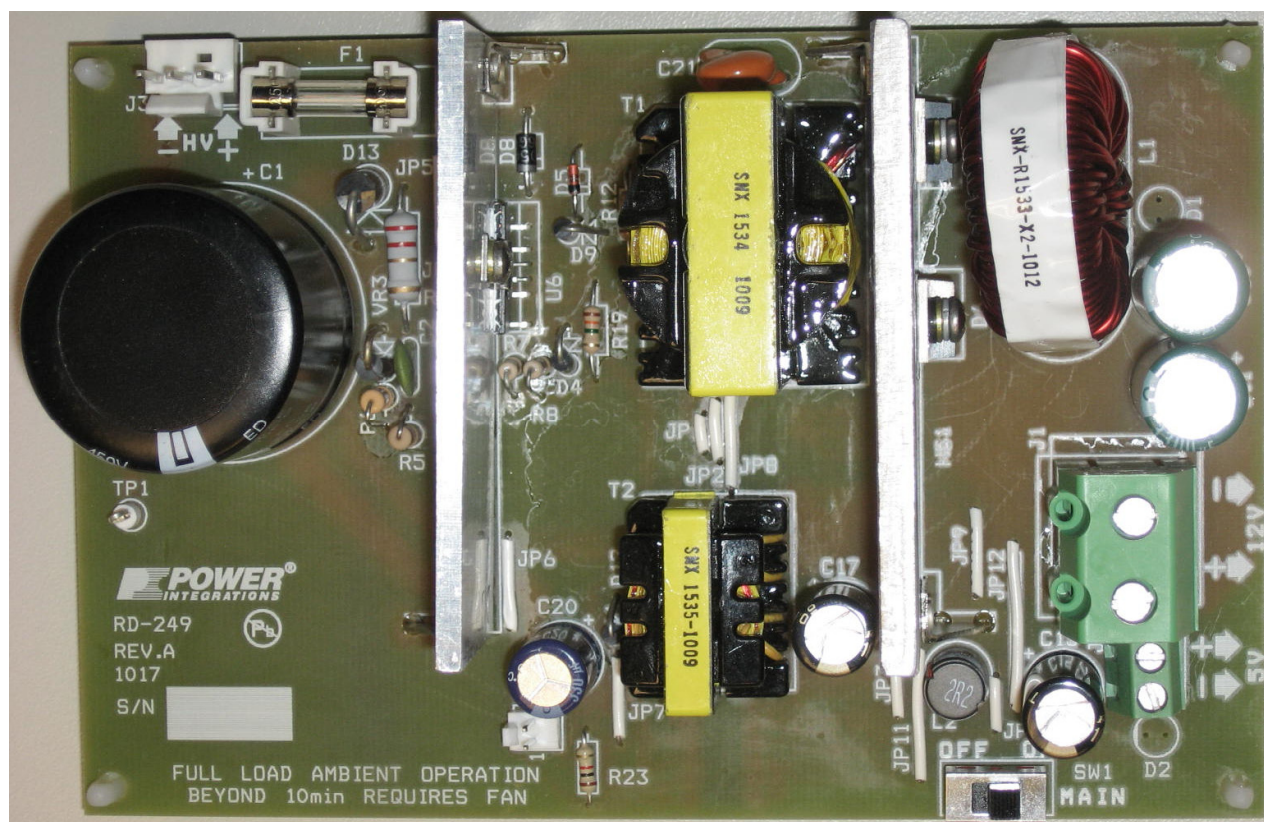


Figure 1 – Populated Circuit Board Photograph.



## 2 Power Supply Specification

The table below represents the minimum acceptable performance of the design. Actual performance is listed in the results section.

| Description                         | Symbol         | Min   | Typ   | Max   | Units | Comment                            |
|-------------------------------------|----------------|-------|-------|-------|-------|------------------------------------|
| <b>Input</b>                        |                |       |       |       |       |                                    |
| Standby only Voltage                | $V_{IN}$       | 100   |       | 420   | VDC   | Equivalent to 85 VAC - 295 VAC     |
| Main and Standby Voltage            | $V_{IN}$       | 300   | 380   | 420   | VDC   |                                    |
| No-load Input Power (324 VDC)       | $P_{IN}$       |       |       | 0.3   | W     | Equivalent to 230 VAC Standby only |
| <b>Output</b>                       |                |       |       |       |       |                                    |
| Output Voltage 1 (standby)          | $V_{OUT1}$     | 4.75  | 5.00  | 5.25  | V     | ±5%, 40 mA minimum load            |
| Output Current 1 (standby)          | $I_{OUT1}$     | 0.04  | 2.9   | 5     | A     | ±10%                               |
| Output Ripple Voltage 1 (standby)   | $V_{RIPPLE1}$  |       |       | 50    | mV    | 20MHz bandwidth                    |
| Output Voltage 2 (main 12 V)        | $V_{OUT2}$     | 11.4  | 12.00 | 12.6  | V     | ±5%, 100mA minimum load            |
| Output Current 2 (main 12 V)        | $I_{OUT2}$     | 0.1   | 25    | 28.33 | A     | ±10%                               |
| Output Ripple Voltage 2 (main 12 V) | $V_{RIPPLE2}$  |       |       | 120   | mV    | 20 MHz bandwidth                   |
| Total Output Power 1                | $P_{OUT1}$     |       | 14.5  | 20    | W     | For Standby only                   |
| Total Output Power 2                | $P_{OUT2}$     |       | 300   |       | W     | For Main12 V only                  |
| Total Output Power 3                | $P_{OUT3}$     |       | 314.5 |       | W     | For both Main and Standby          |
| Total Peak Output Power             | $P_{PEAK}$     |       | 380   |       | W     | For both Main and Standby          |
| <b>Holdup Time</b>                  | $T_{HOLD\_UP}$ | 20 ms |       |       | ms    | For $P_{OUT3}$                     |
| <b>Efficiency</b>                   |                |       |       |       |       |                                    |
| Main and Standby                    | $\eta$         | 86.5  |       |       | %     | 100% Load                          |
| Standby Only                        | $\eta$         |       | 76    |       | %     | 100% Load                          |
| Ambient Temperature                 | $T_{AMB}$      | 0     |       | 50    | °C    | Forced cooling, sea level          |

**Table 1** –Power Supply Specifications Using TFS762HG

Note 1: All measurements performed with 380 VDC input unless otherwise specified

Note 2: For output voltage tolerance and ripple see minimum/maximum allowed current

Note 3: Total peak DC output power will not exceed 365 W at 50 °C with forced cooling

Note 4: Peak Main power is 340 W (excluding Standby)

Note 5: Absolute maximum Standby power is less than 25 W (excluding Main)

Note 6: Full load operation at room temperature beyond 10 minutes requires a 30 CFM fan



### 3 Schematic

Missing from this schematic are any mechanical/assembly part like mounting holes, screws, heat-sink brackets etc.

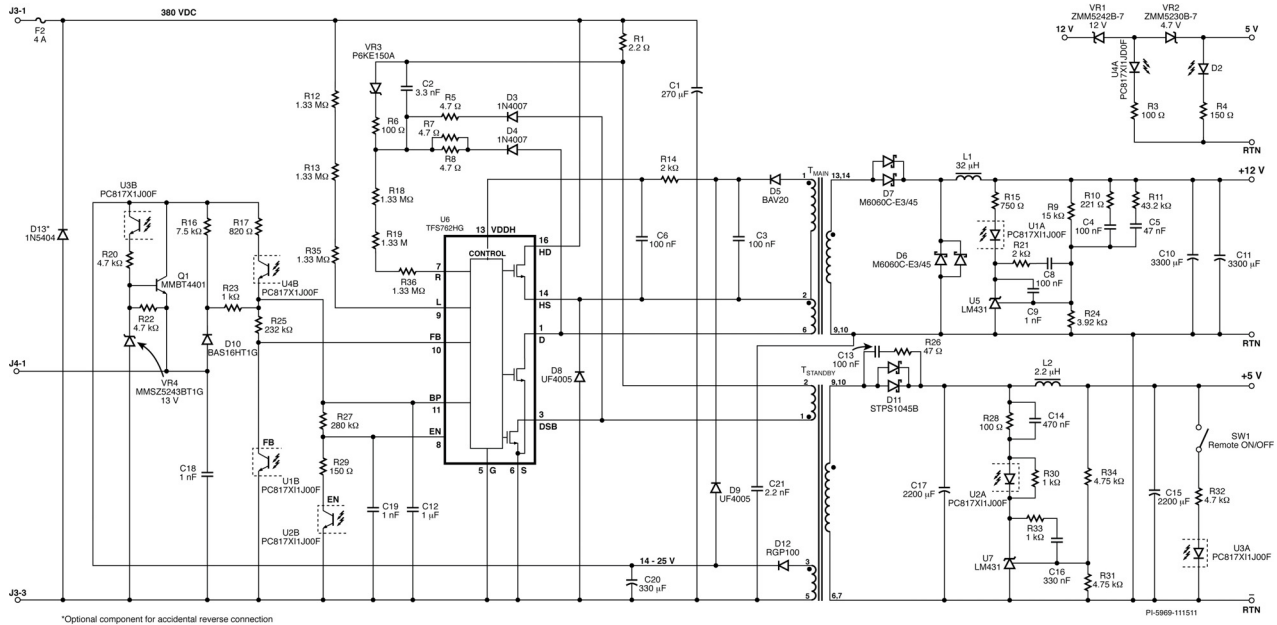


Figure 2 – Schematic.



## 4 Circuit Description

The HiperTFS TFS762HG cost effectively incorporates a low-side 725 V Main MOSFET, a high-side 530 V Main MOSFET and a 725 V Standby MOSFET, main and standby controllers, a high-side driver along with thermal shutdown and other fault protection and other control circuitry in a single package. The device is well suited for high power applications with both main and standby converter (such as PC power supplies). The standby operates over a wide input voltage range. The main converter is intended to accept boosted input voltage from a power-factor correction stage and normally operates over a range from 385 VDC to 300 VDC

### 4.1 Power Input and Filter

This circuit is designed for PC power supplies with a Main output power up to 300 W. Diode D13 provides protection against catastrophic failure in case of reverse input voltage connection which would cause fuse F1 to open. Capacitor C1 is the bulk energy storage element providing energy for at least 20 ms at full load from 385 VDC initial input voltage.

### 4.2 Primary Side

Components C2, R1, R6 and VR3 form a turn-off clamping circuit that limits the drain voltage of U6 for both the standby drain and the drain of the low-side Main Drain of the forward converter. Zener VR3 provides a defined clamp voltage and maintains a maximum voltage (150 V) on clamp capacitor C2. Most of the leakage and magnetizing energy is returned back to converter due to the slow recovery aspect of the general recovery diodes D3 and D4. Shared reset/leakage spike clamp between Main and Standby reduces component count. The Standby is connected via diode D3 and resistor R5 and the Main section is connected through D8 and D4 together with R7 and R8. During the reset time, the Main section is connected to a substantially higher reset voltage than  $V_{IN}$ , hence the Main operating duty cycle of the Main converter can operate above 50% which lowers RMS switch currents without penalizing holdup time.

The BYPASS (BP) pin along with C12 provides a decoupled operating voltage for the HiperTFS controller. At start-up the bypass capacitor is charged from an internal device current source. When the BP pin voltage reaches 5.8 V the standby converter will begin switching and both the +5 V standby output and primary-side bias voltage will begin to rise. The output of the bias/auxiliary supply winding is rectified by diode D12 and filtered by capacitor C20. Output of the bias winding is used to supply power via resistor R16 to the HiperTFS BP pin during standby only operation. Additional current is provided by Q1 and D10 by the primary bias supply when remote-on switch SW1 activates U3A and U3B and commands Q1 into an ON state. In a complete PC power supply application, this voltage is used to supply bias to the PFC controller through J4 connector. The value of R16 is selected to maintain the minimum 700  $\mu$ A required into BP pin to inhibit the internal HiperTFS high voltage current source and thus reduce no-load consumption. Capacitor C12 connected to the BP pin of U6 provides decoupling for the internally



regulated 5.85 V supply. Zener diode VR4 provides a voltage reference for Q1 to regulate the emitter voltage to 12.4 V for a stable 6 mA into BP pin.

The ENABLE (EN) pin is the feedback pin for the Standby controller section. Prior to the start-up a resistor R27 connected from EN to BP can be detected to select one of several internal current limits for Standby section. FEEDBACK (FB) pin resistor R25 can also be used to select one of three Main current limits at start-up in the same manner as the EN pin. Four different resistor values can be used for R27 to select one of the four internal current limit configurations for the Standby section, and three different values for R25 to select one of the three current limit configurations for the Main section. The circuit presented here uses R27 (280 k $\Omega$ ) for a standby  $I_{LIM}$  of 650 mA and R25 for a Main  $I_{LIM}$  of 3.5 A.

The FB pin provides feedback for the Main converter. An increase in current sink from FB pin to ground will lead to a reduction in the operating duty cycle.

Diode D9 is used to provide the initial power for the bootstrap charging C3 and C6 during start-up. During this time the high-side MOSFET HS pin is briefly pulled to Source for 12 ms. Once the main converter begins switching after the initial 12 ms bootstrap delay, diode D5 is used to provide the internal nominal power for the high-side section from the Main transformer support winding, pins 1 and 2. The normal voltage on C6 during normal operation is shunt regulated to approximately 12 V. It is necessary to insure at all times a minimum of 13 V on C3.

Resistors R18, R19, and R36 are used to translate the maximum available OFF time reset voltage into a current for the R pin and compare with the L pin current to compute the maximum allowable duty cycle to prevent saturation and also determines the maximum allowable duty factor as a function of peak on-time flux.

The LINE-SENSE (L) pin provides an input bulk voltage line-sense function. This information is used by the under-voltage and over-voltage detection circuits for both the Main and standby sections. This pin can also be pulled down to SOURCE to implement a remote-ON/OFF of both the Standby and Main supplies simultaneously. Resistors R12, R13, and R35 are used to translate the input voltage into a current for L pin.

### 4.3 Output Rectification

For the Standby section, output rectification is provided by diode D11. A low ESR capacitor, C17, provides filtering with low ripple. Inductor L2 and capacitor C15 form a post-filter to further reduce switching ripple and noise in the output.

For the Main section diode D7 rectifies during Main on-time and diode D6 is the catch diode to provide a current discharge path for the output inductor, L1, during the Main off-time. Inductor L1 together with capacitors C10 and C11 form an output filter out switching output ripple and noise.



#### **4.4 Output Feedback**

For the Standby section, resistor R34 and R31 form a network divider. The output voltage of the power supply is divided and fed to the input terminal of error amplifier U7. The cathode terminal voltage of U2A is controlled by the amplifier inside U7 to maintain the divider voltage to 2.5 V +/-2%. Change in cathode terminal voltage results in a change of the current through optocoupler diode inside U2A, which in turn changes the current through the transistor inside U2B. Capacitor C19 provides strong noise rejection for the EN pin. When the current sinking from the EN pin exceeds the EN pin threshold current, the next switching cycle is inhibited, and when the output voltage falls below the feedback threshold, a conduction cycle is allowed to occur. By adjusting the number of enabled cycles, output regulation is maintained. As the load reduces, the number of enabled cycles decreases lowering the effective switching frequency and scales the switching losses with load. This provides almost constant efficiency down to very light loads, ideal for meeting energy efficiency requirements.

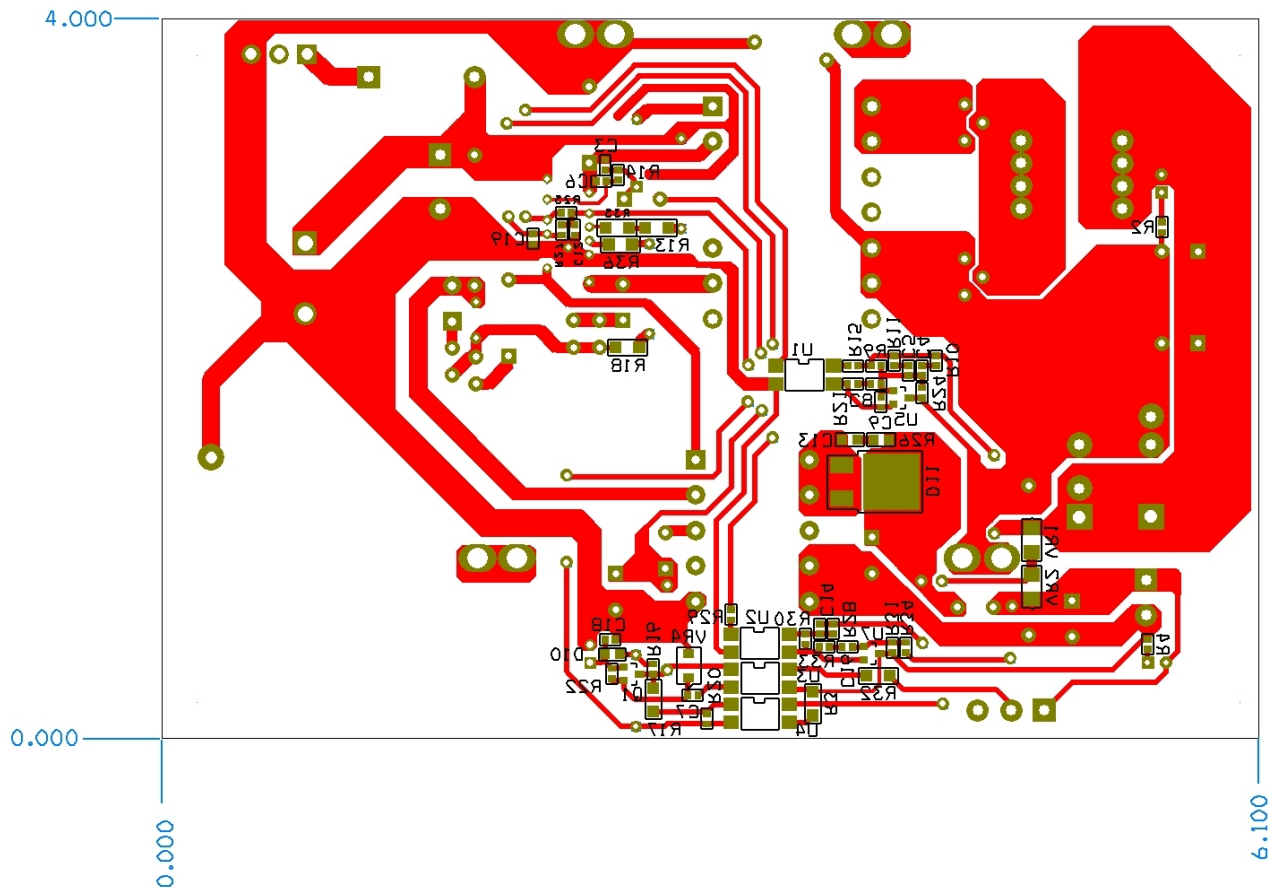
For the Main section, resistors R9 and R24 are employed to provide the DC reference for the U5 error amplifier. In a similar manner, U5 controls the optocoupler U1 used to adjust the operating duty cycle through the current sink from the FB pin with the main difference being the FB pin current controls the duty cycle of the main converter in a linear manner versus the whole cycle on/off control of the standby converter.

#### **4.5 Output Overvoltage Protection**

The output OV protection for both Main and Standby is provided through optocoupler U4. If the feedback loop is broken or for any other internal or external reason, the output voltage increases over the maximum allowed limit, VR1 and/or VR2 are used to activate the protection circuit built around U4. When the output of U4B turns on, the current flow into the BP pin exceeds the latching shutdown threshold current of 15 mA. This will trigger the latching shutdown feature of HiperTFS and the device stops switching, protecting the output. The latching condition disables switching until the latch is reset with source current into the L pin below 10  $\mu$ A.



## 5 PCB Layout



**Figure 3 – Printed Circuit Layout, Bottom Side.**



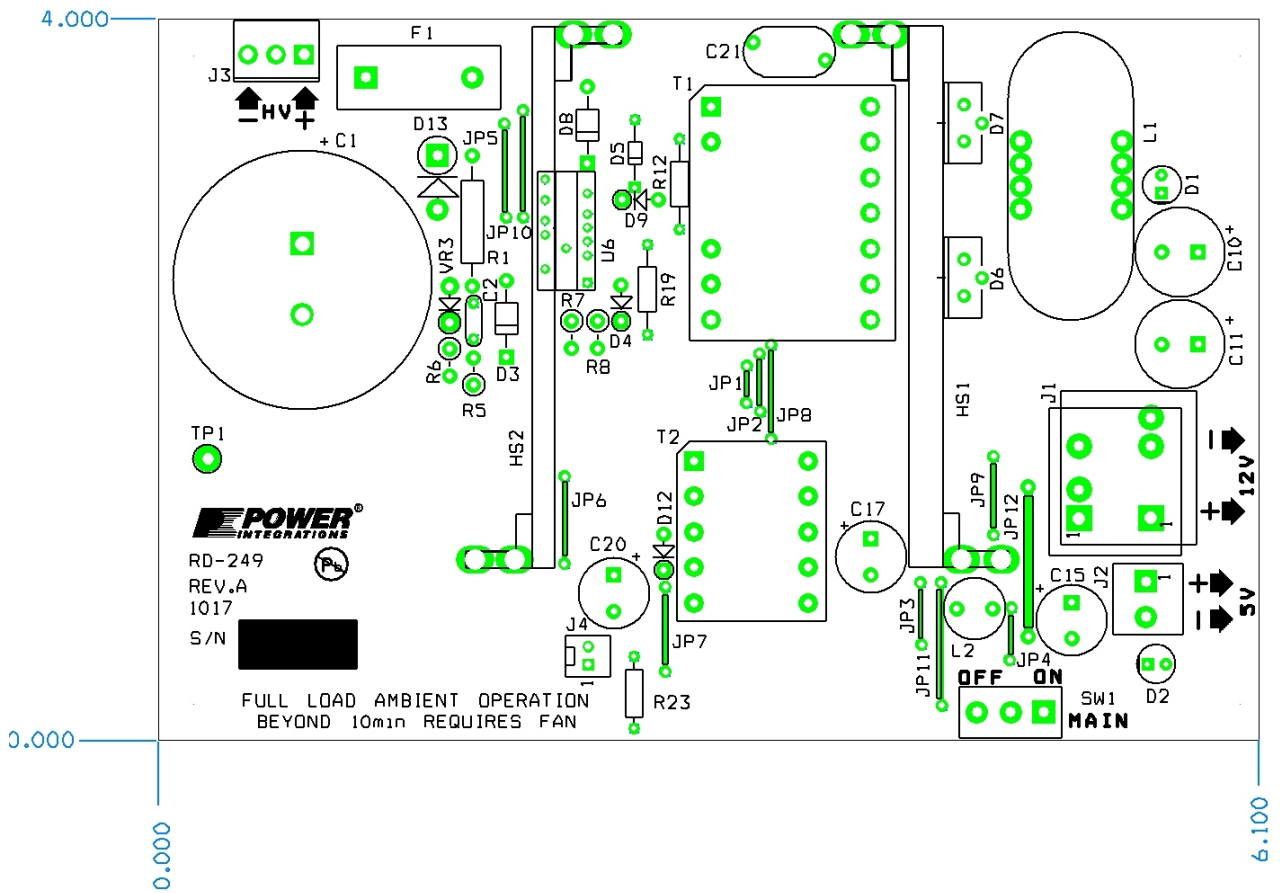


Figure 4 – Printed Circuit Layout, Top Side.

## 6 Bill of Materials

| Item | Qty | Ref Des                                            | Description                                                                 | Mfg Part Number    | Mfg                |
|------|-----|----------------------------------------------------|-----------------------------------------------------------------------------|--------------------|--------------------|
| 1    | 1   | C1                                                 | 270 $\mu$ F, 450 V, Electrolytic, (35 x 35)                                 | EET-ED2W271EA      | Panasonic          |
| 2    | 1   | C2                                                 | 3.3 nF, 1 kV, Disc Ceramic                                                  | NCD332M1KVZ5U      | NIC                |
| 3    | 4   | C3 C4 C6 C8                                        | 100 nF 25 V, Ceramic, X7R, 0603                                             | ECJ-1VB1E104K      | Panasonic          |
| 4    | 1   | C5                                                 | 47 nF 16 V, Ceramic, X7R, 0603                                              | ECJ-1VB1C473K      | Panasonic          |
| 5    | 1   | C7                                                 | 470 pF 50 V, Ceramic, X7R, 0603                                             | ECJ-1VC1H471J      | Panasonic          |
| 6    | 3   | C9 C18 C19                                         | 1000 pF, 100 V, Ceramic, COG, 0603                                          | C1608C0G2A102J     | TDK                |
| 7    | 2   | C10 C11                                            | 3300 $\mu$ F, 16 V, Electrolytic, Very Low ESR, 15 m $\Omega$ , (12.5 x 35) | EKZE160ELL332MK35S | Nippon Chemi-Con   |
| 8    | 1   | C12                                                | 1 $\mu$ F, 16 V, Ceramic, X5R, 0603                                         | GRM188R61C105KA93D | Murata             |
| 9    | 1   | C13                                                | 1 nF, 100 V, Ceramic, X7R, 0805                                             | ECJ-2VB2A102K      | Panasonic          |
| 10   | 1   | C14                                                | 470 nF, 50 V, Ceramic, Y5G, 0603                                            | C1608Y5V1H474Z     | TDK                |
| 11   | 2   | C15 C17                                            | 2200 $\mu$ F, 10 V, Electrolytic, Low ESR, (10 x 25)                        | 10MCZ1000M10X25    | Rubycon            |
| 12   | 1   | C16                                                | 330 nF, 16 V, Ceramic, Y5G, 0603                                            | ECJ-1VF1C334Z      | Panasonic          |
| 13   | 1   | C20                                                | 330 $\mu$ F, 35 V, Electrolytic, Low ESR, 68 m $\Omega$ , (10 x 16)         | ELXZ350ELL331MJ16S | Nippon Chemi-Con   |
| 14   | 1   | C21                                                | 2.2 nF, Ceramic, Y1                                                         | 440LD22-R          | Vishay             |
| 15   | 1   | D1                                                 | LED, Yellow, 5 mm, 585 nm, 30 mcd                                           | SSL-LX5093YD       | Lumex Opto         |
| 16   | 1   | D2                                                 | LED, Green, 5 mm, 565 nm, 30 mcd                                            | SSL-LX5093GD       | Lumex Opto         |
| 17   | 2   | D3 D4                                              | 1000 V, 1 A, Rectifier, DO-41                                               | 1N4007-E3/54       | Vishay             |
| 18   | 1   | D5                                                 | 200 V, 200 mA, Fast Switching, 50 ns, DO-35                                 | BAV20              | Vishay             |
| 19   | 2   | D6 D7                                              | 60 V, 60 A, Dual Schottky, TO-220AB                                         | M6060C-E3/45       | Vishay             |
| 20   | 2   | D8 D9                                              | 600 V, 1 A, Ultrafast Recovery, 75 ns, DO-41                                | UF4005-E3          | Vishay             |
| 21   | 1   | D10                                                | 75 V, 200 mA, Rectifier, SOD323                                             | BAS16HT1G          | ON Semi            |
| 22   | 1   | D11                                                | 45 V, 10 A, Schottky Low Drop, SMD, DPAK                                    | STPS1045B-TR       | ST                 |
| 23   | 1   | D12                                                | 50 V, 1 A, Ultrafast Recovery, 50 ns, DO-41                                 | UF4001-E3          | Vishay             |
| 24   | 1   | D13                                                | OBS non RoHS use 15-00796-00. 400 V, 3 A, Rectifier, DO-201AD               | 1N5404             | Vishay             |
| 25   | 1   | ESIP CLIP1                                         | Heatsink Hardware, Edge Clip xxN (xx lbs) 14.33 mm L x 6.35 mm W            | TRK-24             | Kang Tang Hardware |
| 26   | 1   | F1                                                 | FUSEHOLDER OPEN 5 X 20 MM PC MNT                                            | 64900001039        | Wickmann           |
| 27   | 1   | F2                                                 | 6.3 A, 250 V, Fast, 5 mm x 20 mm, Cartridge                                 | 021706.3HXP        | Littlefuse         |
| 28   | 1   | GREASE1                                            | Thermal Grease, Silicone, 5 oz Tube                                         | CT40-5             | ITW Chemtronics    |
| 29   | 2   | HEATSINK BRACKET RIGHT1<br>HEATSINK BRACKET RIGHT2 | Bracket, Heatsink, Right                                                    |                    | Custom             |
| 30   | 2   | HEATSINK BRACKET3<br>HEATSINK BRACKET4             | Bracket, Heatsink, Left                                                     |                    | Custom             |
| 31   | 2   | HS PAD1 HS PAD2                                    | HEATSINK PAD, TO-220, Sil-Pad 1000                                          | 1009-58            | Bergquist          |
| 32   | 1   | HS1                                                | HEATSINK, RDK249-Diode-Hsink, Alum 5052, 3.00" L x 1.650" W x 0.187" Thk    | 61-00041-00        | Custom             |



|    |   |                           |                                                                         |                    |                 |
|----|---|---------------------------|-------------------------------------------------------------------------|--------------------|-----------------|
| 33 | 1 | HS2                       | HEATSINK, RDK249-eSIP-Hsink, Alum 5052, 3.00" L x 1.650" W x 0.125" Thk | 61-00042-00        | Custom          |
| 34 | 1 | J1                        | 2 Position (1 x 2) header, 10.16 mm (0.400) pitch, Vertical             | 1706785            | Phoenix Contact |
| 35 | 1 | J1_OPTIO                  | 2 Position (1 x 2) header, 10.16 mm (0.400) pitch, Vertical             | 39910-0102         | Molex           |
| 36 | 1 | J2                        | 2 Position (1 x 2) header, 5 mm (0.196) pitch, Vertical                 | 1715022            | Phoenix Contact |
| 37 | 1 | J3                        | CONN HEADER 3POS (1x3).156 VERT TIN                                     | 26-64-4030         | Molex           |
| 38 | 1 | J4                        | 2 Position (1 x 2) header, 0.1 pitch, Vertical                          | 22-23-2021         | Molex           |
| 39 | 1 | JP1                       | Wire Jumper, Insulated, 22 AWG, 0.2 in                                  | C2004-12-02        | Gen Cable       |
| 40 | 3 | JP2 JP3 JP4               | Wire Jumper, Insulated, 22 AWG, 0.3 in                                  | C2004-12-02        | Gen Cable       |
| 41 | 5 | JP5 JP6 JP7 JP8 JP9       | Wire Jumper, Insulated, 22 AWG, 0.5 in                                  | C2004-12-02        | Gen Cable       |
| 42 | 2 | JP10 JP11                 | Wire Jumper, Insulated, 22 AWG, 0.7 in                                  | C2004-12-02        | Gen Cable       |
| 43 | 1 | JP12                      | Wire Jumper, Insulated, 22 AWG, 0.8 in                                  | C2004-12-02        | Gen Cable       |
| 44 | 1 | JP13                      | 0 R, 5%, 1/10 W, Thick Film, 0603                                       | ERJ-3GEY0R00V      | Panasonic       |
| 45 | 1 | L1                        | 32 $\mu$ H, xA, Power Iron Toroid, 8P                                   | SNX-R1533          | Santronics USA  |
| 46 | 1 | L2                        | 2.2 $\mu$ H, 6.0 A                                                      | RFB0807-2R2L       | Coilcraft       |
| 47 | 4 | POST-CRKT_BRD_6-32_HEX1-4 | Post, Circuit Board, Female, Hex, 6-32, snap, 0.375L, Nylon             | 561-0375A          | Eagle Hardware  |
| 48 | 1 | Q1                        | NPN, Small Signal BJT, GP SS, 40 V, 0.6 A, SOT-23                       | MMBT4401LT1G       | On Semi         |
| 49 | 1 | R1                        | 2.2 $\Omega$ , 5%, 1 W, Metal Film, Fusible                             | NFR0100002208JR500 | Vishay          |
| 50 | 1 | R2                        | 470 $\Omega$ , 5%, 1/10 W, Thick Film, 0603                             | ERJ-3GEYJ471V      | Panasonic       |
| 51 | 1 | R3                        | 100 $\Omega$ , 5%, 1/4 W, Thick Film, 1206                              | ERJ-8GEYJ101V      | Panasonic       |
| 52 | 2 | R4 R29                    | 150 $\Omega$ , 5%, 1/10 W, Thick Film, 0603                             | ERJ-3GEYJ151V      | Panasonic       |
| 53 | 3 | R5 R7 R8                  | 4.7 $\Omega$ , 5%, 1/2 W, Carbon Film                                   | CFR-50JB-4R7       | Yageo           |
| 54 | 1 | R6                        | 100 $\Omega$ , 5%, 1/2 W, Carbon Film                                   | CFR-50JB-100R      | Yageo           |
| 55 | 1 | R9                        | 15 k $\Omega$ , 5%, 1/10 W, Thick Film, 0603                            | ERJ-3GEYJ153V      | Panasonic       |
| 56 | 1 | R10                       | 221 $\Omega$ , 1%, 1/16 W, Thick Film, 0603                             | ERJ-3EKF2210V      | Panasonic       |
| 57 | 1 | R11                       | 43.2 k $\Omega$ , 1%, 1/16 W, Thick Film, 0603                          | ERJ-3EKF4322V      | Panasonic       |
| 58 | 2 | R12 R19                   | 1.33 M $\Omega$ , 1%, 1/4 W, Metal Film                                 | 271-1.33M/REEL-RC  | Xicon           |
| 59 | 4 | R13 R18 R35 R36           | 1.33 M $\Omega$ , 1%, 1/4 W, Thick Film, 1206                           | MCR18EZH1334       | Rohm            |
| 60 | 1 | R14                       | 2 k $\Omega$ , 5%, 1/10 W, Thick Film, 0603                             | ERJ-3GEYJ202V      | Panasonic       |
| 61 | 1 | R15                       | 750 $\Omega$ , 1%, 1/16 W, Thick Film, 0603                             | ERJ-3EKF7500V      | Panasonic       |
| 62 | 1 | R16                       | 7.5 k $\Omega$ , 1%, 1/16 W, Thick Film, 0603                           | ERJ-3EKF7501V      | Panasonic       |
| 63 | 1 | R17                       | 820 $\Omega$ , 5%, 1/4 W, Thick Film, 1206                              | ERJ-8GEYJ821V      | Panasonic       |
| 64 | 2 | R20 R22                   | 4.7 k $\Omega$ , 5%, 1/10 W, Thick Film, 0603                           | ERJ-3GEYJ472V      | Panasonic       |
| 65 | 1 | R21                       | 2 k $\Omega$ , 1%, 1/16 W, Thick Film, 0603                             | ERJ-3EKF2001V      | Panasonic       |
| 66 | 1 | R23                       | 1 k $\Omega$ , 5%, 1/4 W, Carbon Film                                   | CFR-25JB-1K0       | Yageo           |
| 67 | 1 | R24                       | 3.92 k $\Omega$ , 1%, 1/16 W, Thick Film, 0603                          | ERJ-3EKF3921V      | Panasonic       |
| 68 | 1 | R25                       | 232 k $\Omega$ , 1%, 1/16 W, Thick Film, 0603                           | ERJ-3EKF2323V      | Panasonic       |
| 69 | 1 | R26                       | 200 $\Omega$ , 5%, 1/4 W, Thick Film, 1206                              | ERJ-8GEYJ201V      | Panasonic       |
| 70 | 1 | R27                       | 280 k $\Omega$ , 1%, 1/16 W, Thick Film, 0603                           | ERJ-3EKF2803V      | Panasonic       |
| 71 | 1 | R28                       | 100 $\Omega$ , 5%, 1/10 W, Thick Film, 0603                             | ERJ-3GEYJ101V      | Panasonic       |
| 72 | 2 | R30 R33                   | 1 k $\Omega$ , 5%, 1/10 W, Thick Film, 0603                             | ERJ-3GEYJ102V      | Panasonic       |



|    |   |                                |                                                                                  |                         |                             |
|----|---|--------------------------------|----------------------------------------------------------------------------------|-------------------------|-----------------------------|
| 73 | 2 | R31 R34                        | 4.75 k $\Omega$ , 1%, 1/16 W, Thick Film, 0603                                   | ERJ-3EKF4751V           | Panasonic                   |
| 74 | 1 | R32                            | 4.7 k $\Omega$ , 5%, 1/4 W, Thick Film, 1206                                     | ERJ-8GEYJ472V           | Panasonic                   |
| 75 | 4 | RIVET1 RIVET2<br>RIVET3 RIVET4 | Rivet, Al, .093 Dia x 0.187 (3/16) L, 100 Deg Countersunk, soft, 1100-F Aluminum |                         | Olander                     |
| 76 | 4 | RIVET5 RIVET6<br>RIVET7 RIVET8 | Rivet, Al, .093 Dia x 0.250 (1/4) L, 100 Deg Countersunk, soft, 1100-F Aluminum  |                         | Olander                     |
| 77 | 1 | SCREW1                         | SCREW MACHINE PHIL 4-40 X 1/4 SS                                                 | PMSSS 440 0025 PH       | Building Fasteners          |
| 78 | 2 | SCREW2 SCREW3                  | SCREW MACHINE PHIL 4-40 X 5/16 SS                                                | PMSSS 440 0031 PH       | Building Fasteners          |
| 79 | 1 | SW1                            | SLIDE MINI SPDT PC MNT AU                                                        | 1101M2S3CBE2            | ITT Ind/C&Kdiv              |
| 80 | 1 | T1                             | Custom Transformer, Vertical, 14 pins Bobbin                                     | SNX-R1534<br>YC-3508    | Santronics USA<br>Ying Chin |
| 81 | 1 | T2                             | Custom Transformer, Vertical, 10 Pins Bobbin                                     | SNX-R1535<br>YW-360-02B | Santronics USA<br>Yih-Hwa   |
| 82 | 1 | TP1                            | Test Point, WHT, THRU-HOLE MOUNT                                                 | 5012                    | Keystone                    |
| 83 | 4 | U1 U2 U3 U4                    | Optocoupler, TRAN OUT 4-SMD                                                      | PC817XI1J00F            | Sharp                       |
| 84 | 2 | U5 U7                          | OBS see 45-00144-00 2.495 V Shunt Regulator IC, 2%, -40 to 85C, SOT23            | LM431AIM                | National Semiconductor      |
| 85 | 1 | U6                             | TFS762HG, ESIP16/12                                                              | TFS762HG                | Power Integrations          |
| 86 | 1 | VR1                            | 12 V, 5%, 500 mW, DO-213AA (MELF)                                                | ZMM5242B-7              | Diodes Inc                  |
| 87 | 1 | VR2                            | 4.7 V, 5%, 500 mW, DO-213AA (MELF)                                               | ZMM5230B-7              | Diodes Inc                  |
| 88 | 1 | VR3                            | 150 V, 5 W, 5%, TVS, DO204AC (DO-15)                                             | P6KE150A                | LittleFuse                  |
| 89 | 1 | VR4                            | 13 V, 5%, 500 mW, SOD-123                                                        | MMSZ5243BT1G            | ON Semi                     |
| 90 | 3 | WASHER 1, 2, 3                 | Washer, Lk, #4 SS                                                                | 4NSLWS                  | Olander                     |
| 91 | 2 | WASHER 4, 5                    | Washer FLAT #4 SS                                                                | FWSS 004                | Building Fasteners          |
| 92 | 2 | WASHER 6, 7                    | Washer, Shoulder, Nylon, #4                                                      | 3049                    | Keystone                    |



## 7 Standby Transformer Specification

### 7.1 Electrical Diagram

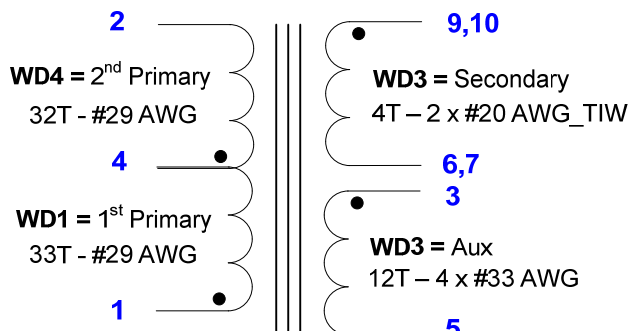


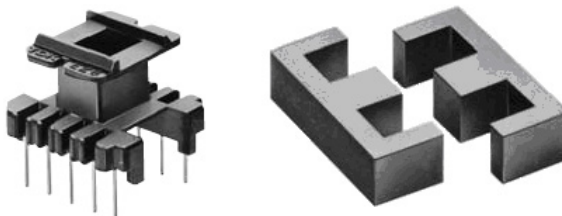
Figure 5 – Transformer Electrical Diagram.

### 7.2 Electrical Specifications

|                            |                                                                                  |                        |
|----------------------------|----------------------------------------------------------------------------------|------------------------|
| <b>Electrical Strength</b> | 1 second, 60 Hz, from pins 1-5 to pins 6-10                                      | 3000 VAC               |
| <b>Primary Inductance</b>  | Pins 1-2, all other windings open, measured at 100 kHz, 0.4 V <sub>RMS</sub>     | 850 $\mu$ H, $\pm$ 10% |
| <b>Resonant Frequency</b>  | Pins 1-2, all other windings open                                                | 2.15 MHz Min           |
| <b>Leakage Inductance</b>  | Pins 1-2, with secondary pins shorted, measured at 100 kHz, 0.4 V <sub>RMS</sub> | 18 $\mu$ H Max         |

### 7.3 Materials

| Item | Description                                                        |
|------|--------------------------------------------------------------------|
| [1]  | Core: TDK EE25 part #: PC40EE25.4-Z                                |
| [2]  | Bobbin: EE25, Vertical, 10 pins, (5/5), Yhi Hwa part #: YW-360-02B |
| [3]  | Magnet wire: #29 AWG                                               |
| [4]  | Magnet wire: #33 AWG                                               |
| [5]  | Magnet wire: #20 AWG Triple Insulated Wire                         |
| [6]  | Tape: 3M 1298 Polyester Film, 2 mils thick, 10.8 mm wide           |
| [7]  | Varnish                                                            |



## 7.4 Transformer Build Diagram

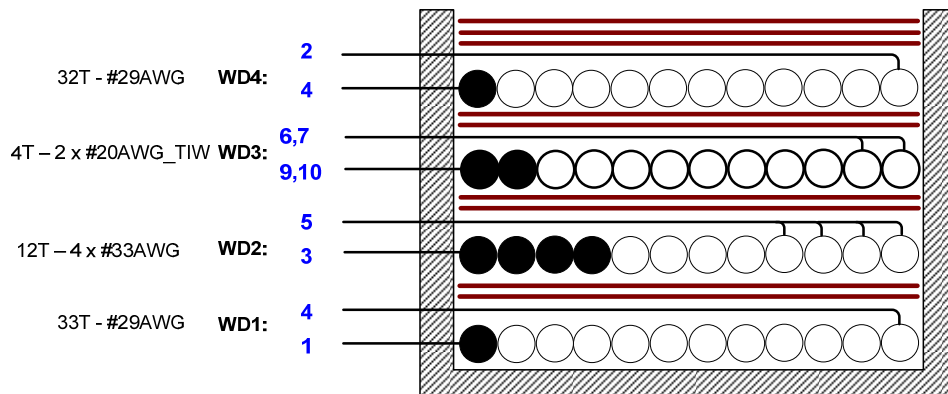


Figure 6 – Transformer Build Diagram.

## 7.5 Transformer Construction

|                                    |                                                                                                                                                                                               |
|------------------------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| <b>Winding Preparation</b>         | Position the bobbin on the mandrel such that the pin side is on the left side of bobbin mandrel. Winding direction is clock-wise direction                                                    |
| <b>WD1: 1<sup>st</sup> Primary</b> | Start at pin 1, wind 33 turns of wire item [3] from left to right with tight tension in one layer, at the last turn bring the wire back to the left and terminate at pin 4                    |
| <b>Insulation</b>                  | 2 layers of tape item [6]                                                                                                                                                                     |
| <b>WD2: Auxiliary</b>              | Start at pin 3, wind 12 quad-filar turns of wire item [4] from left to right also with tight tension in one layer, at the last turn bring the wire back to the left and terminate at pin 5    |
| <b>Insulation</b>                  | 2 layers of tape item [6]                                                                                                                                                                     |
| <b>WD3: Secondary</b>              | Start at pin 9, 10 wind 4 bi-filar turns of wire item [5] from left to right also with tight tension in one layer, at the last turn bring the wire back to the left and terminate at pin 6, 7 |
| <b>Insulation</b>                  | 2 layers of tape item [6]                                                                                                                                                                     |
| <b>WD4: 2<sup>nd</sup> Primary</b> | Start at pin 4, wind 32 turns of wire item [3] from right to left with tight tension in one layer, at the last turn bring the wire back to the right and terminate at pin 2                   |
| <b>Insulation</b>                  | 3 layers of tape item [6]                                                                                                                                                                     |
| <b>Finish</b>                      | Assemble, grind the cores to get 2.15 mH and secure with tape. Varnish [7]                                                                                                                    |



## 8 Main Transformer Specification

### 8.1 Electrical Diagram

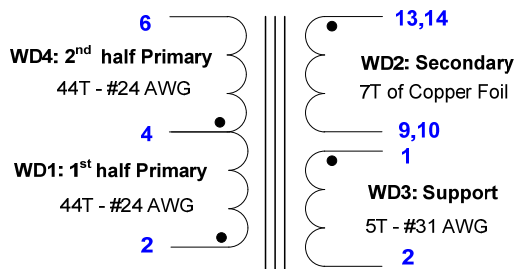


Figure 7 – Transformer Electrical Diagram.

### 8.2 Electrical Specifications

|                            |                                                                            |                |
|----------------------------|----------------------------------------------------------------------------|----------------|
| <b>Electrical Strength</b> | 1 second, 60 Hz, from pins 1-7 to pins 8-14                                | 3000 VAC       |
| <b>Primary Inductance</b>  | Pins 2-6, all other open, measured at 50 kHz, 0.4 V <sub>RMS</sub>         | 23 mH, ±25%    |
| <b>Resonant Frequency</b>  | Pins 2-6, all other open                                                   | 200 kHz (Min.) |
| <b>Primary Leakage</b>     | Pins 2-6, with pins 8-14 shorted, measured at 50 kHz, 0.4 V <sub>RMS</sub> | 25 µH (Max.)   |

### 8.3 Materials

| Item | Description                                                                           |
|------|---------------------------------------------------------------------------------------|
| [1]  | Core: TDK part #:PC40HEER35-Z                                                         |
| [2]  | Bobbin: EER35, Vertical, 14 pins, (7/7), YingChin part #: YC-3508                     |
| [3]  | Magnet wire: #24 AWG Heavy Nyleze (Solderable Polyurethane-Nylon, Class 130°C Type B) |
| [4]  | Magnet wire: #31 AWG Heavy Nyleze (Solderable Polyurethane-Nylon, Class 130°C Type B) |
| [5]  | Copper Foil: 8 mils thick (see Fig. 3)                                                |
| [6]  | Tape: 3M 1298 Polyester Film, 2 mil thick, 25.5 mm wide                               |
| [7]  | Tape: 3M 1298 Polyester Film, 2 mil thick, 36.0 mm wide                               |
| [8]  | Tape: 3M 44 Margin tape (cream), 3.0 mm wide                                          |
| [9]  | Tape: 3M 44 Margin tape (cream), 6.0 mm wide                                          |
| [10] | Varnish                                                                               |



## 8.4 Transformer Build Diagram

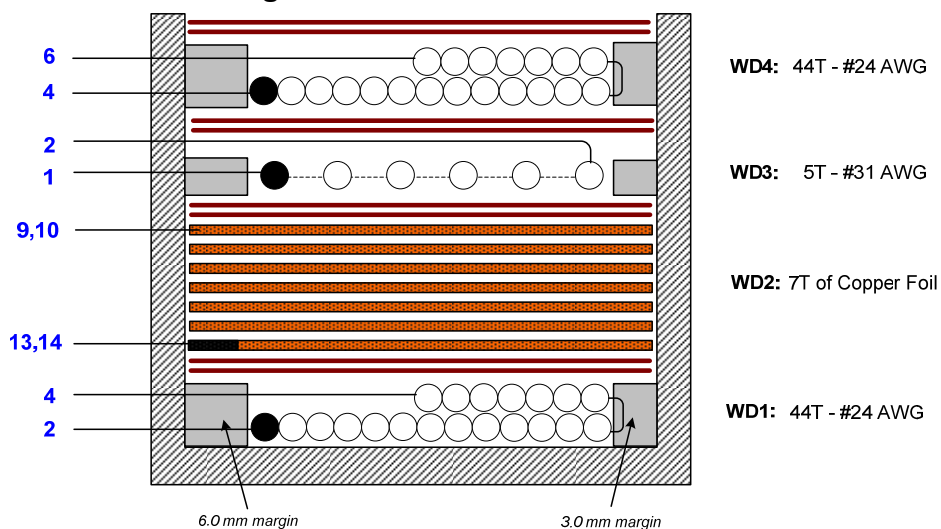


Figure 8 – Transformer Build Diagram.

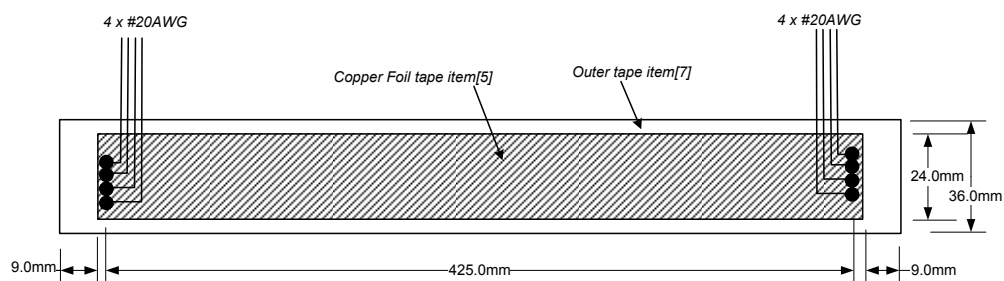


Figure 9 – Copper Foil Preparation.



### 8.5 Transformer Construction

|                                         |                                                                                                                                            |
|-----------------------------------------|--------------------------------------------------------------------------------------------------------------------------------------------|
| <b>Winding Preparation</b>              | Position the bobbin on the mandrel such that the pin side is on the left side of bobbin mandrel. Winding direction is clock-wise direction |
| <b>Margin Tape</b>                      | Place margin tape 6.0 mm item [9] for the left side and 3.0 mm item [8] for the right side matching with height of WD1                     |
| <b>WD1: 1<sup>st</sup> Half Primary</b> | Start at pin 2, wind 44 turns of wire item [3] from left to right and right to left in 1 ½ layers and terminate at pin 4                   |
| <b>Insulation</b>                       | 2 layers of tape item [6]                                                                                                                  |
| <b>Copper Foil</b>                      | Prepare the copper foil as in above figure                                                                                                 |
| <b>WD2: Secondary</b>                   | Use copper foil item [5], start at pins 13, 14, wind 7 turns with tight tension and end at pins 9, 10                                      |
| <b>Insulation</b>                       | 2 layers of tape item [6]                                                                                                                  |
| <b>Margin Tape</b>                      | Place margin tape 6.0mm item [9] for the left side and 3.0mm item [8] for the right side matching with height of WD3                       |
| <b>WD3: Support</b>                     | Start at pin 1, wind 5 turns item [4] from left to right, at the last turn bring the wire back to the left to terminate at pin 2           |
| <b>Insulation</b>                       | 2 layers of tape item [6]                                                                                                                  |
| <b>Margin Tape</b>                      | Place margin tape 6.0 mm item [9] for the left side and 3.0 mm item [8] for the right side matching with height of WD4                     |
| <b>WD4: 2<sup>nd</sup> Half Primary</b> | Start at pin 4, wind 44 turns of wire item [3] from left to right and right to left in 1 ½ layers and terminate at pin 6                   |
| <b>Insulation</b>                       | 2 layers of tape item [6]                                                                                                                  |
| <b>Finish</b>                           | Assemble and secure the cores with tape. Varnish item [7]                                                                                  |



## 9 Main Output Inductor Specification

### 9.1 Electrical Diagram

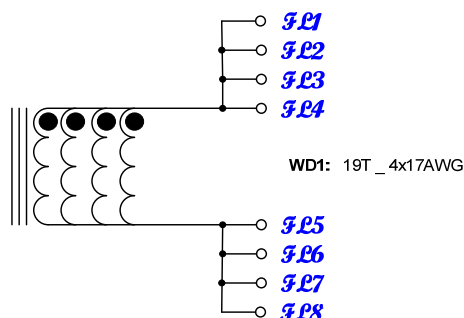


Figure 10 – Inductor Electrical Diagram.

### 9.2 Electrical Specifications

|                           |                              |                           |
|---------------------------|------------------------------|---------------------------|
| Core Effective Inductance |                              | AL = 95 nH/N <sup>2</sup> |
| Inductance (LCM)          | Pins 1-2 measured at 100 kHz | 35.8 $\mu$ H $\pm$ 10%    |

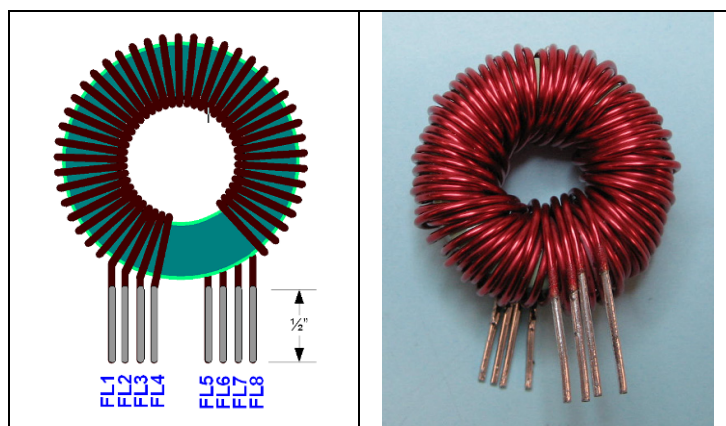
### 9.3 Materials

| Item | Description                                    |
|------|------------------------------------------------|
| [1]  | Toroid: Micrometals, part#: T132-52            |
| [2]  | Magnet Wire: #17 AWG, solderable double coated |

### 9.4 Winding Instructions

- Use 4 wires of item [2] about 100 cm long, wind 19 turns in ~2 layers firmly and in one direction. Start with FL1, FL2, FL3, FL4, end with FL5, FL6, FL7, FL8, and leave ~ 1/2" long.
- Tin all leads ~1/2"

### 9.5 Inductor Illustrations



## 10 Transformer Design Spreadsheet

(Note – Output current is made 4.20 A in the spreadsheet to account for load on the auxiliary output)

| HiperTFS_Two-switch_Forward_092110<br>; Rev.1.04; Copyright<br>Power Integrations 2010 | INPUT  | INFO  | OUTPUT       | UNIT     | HiperTFS_092110 Two-switch Forward<br>Transformer Design Spreadsheet                                           |
|----------------------------------------------------------------------------------------|--------|-------|--------------|----------|----------------------------------------------------------------------------------------------------------------|
| <b>HiperTFS MAIN OUTPUT (TWO-SWITCH FORWARD STAGE)<br/>OUTPUT VOLTAGE AND CURRENT</b>  |        |       |              |          |                                                                                                                |
| VMAIN                                                                                  | 12.00  |       |              | V        | Main output voltage                                                                                            |
| IMAIN                                                                                  | 25.00  |       |              | A        | Main output current                                                                                            |
| VOUT2                                                                                  |        |       |              | V        | Output2 voltage                                                                                                |
| IOUT2                                                                                  |        |       |              | A        | Output2 current                                                                                                |
| <b>POST REGULATED OUTPUT</b>                                                           |        |       |              |          |                                                                                                                |
| Post Regulator                                                                         | NONE   | Info  |              |          | !!!! Info. No Selection for post-regulator - select 'NONE' if not using post-regulator                         |
| V_SOURCE                                                                               |        |       |              | V        | Select source of input voltage for post regulator                                                              |
| VOUT3                                                                                  |        |       | 0.0          | V        | Enter postregulator output voltage                                                                             |
| IOUT3                                                                                  |        |       | 0.0          | A        | Enter post regulator output current                                                                            |
| n_PR                                                                                   |        |       | 1            |          | Enter postregulator efficiency (Buck only)                                                                     |
| <b>COUPLED-INDUCTOR (LOW POWER) DERIVED OUTPUT</b>                                     |        |       |              |          |                                                                                                                |
| VOUT4                                                                                  | 12.00  |       |              | V        | Coupled-Inductor derived (low power) output voltage (typically -12 V)                                          |
| IOUT4                                                                                  | 0.10   |       |              | A        | Coupled-Inductor derived (low power) output current                                                            |
| POUT(Main)                                                                             |        |       | 301.2        | W        | Total output power (Main converter)                                                                            |
| POUT_PEAK(Main)                                                                        | 340.00 |       | 340.0        | W        | Peak Output power(Main converter). If there is no peak power requirement enter value equal to continuous power |
| POUT(Standby)                                                                          |        |       | 10.3         | W        | Continuous output power from Standby power supply                                                              |
| POUT_PEAK(Standby)                                                                     |        |       | 14.5         | W        | Peak output power from Standby section                                                                         |
| <b>POUT(System Total)</b>                                                              |        |       | <b>311.5</b> | <b>W</b> | <b>Total system continuous output power</b>                                                                    |
| POUT_PEAK(System Total)                                                                |        |       |              | W        | Total system peak output power                                                                                 |
| VBIAS                                                                                  | 17.00  |       |              | V        | DC bias voltage from main transformer aux winding                                                              |
| <b>INPUT VOLTAGE AND UV/OV</b>                                                         |        |       |              |          |                                                                                                                |
| CIN                                                                                    |        |       | 269.92       | uF       | Input Capacitance. To increase CMIN, increase T_HOLDUP                                                         |
| T_HOLDUP                                                                               |        |       | 20.00        | ms       | Holdup time                                                                                                    |
| VMIN                                                                                   |        |       | 300          | V        | Minimum input voltage to guarantee output regulation                                                           |
| VNOM                                                                                   |        |       | 380          | V        | Nominal input voltage                                                                                          |
| VMAX                                                                                   |        |       | 420          | V        | Maximum DC input voltage                                                                                       |
| UV / OV / UVOV                                                                         |        | min   | max          |          |                                                                                                                |
| VUV OFF                                                                                |        | 236.0 | 287.9        | V        | Minimum undervoltage On-Off threshold                                                                          |
| VUV ON                                                                                 |        | 300.0 | 344.7        | V        | Maximum undervoltage Off-On threshold (turn-on)                                                                |
| VOV ON                                                                                 |        | 480.4 | -            | V        | Minimum overvoltage Off-On threshold                                                                           |
| VOV OFF                                                                                |        | 664.5 | -            | V        | Minimum overvoltage On-Off threshold (turn-off)                                                                |
| RR                                                                                     |        |       | 4.00         | M-ohm    | R pin resistor                                                                                                 |
| RL                                                                                     | 4      |       | 4.00         | M-ohm    | Line Sense resistor value (L-pin) - goal seek (VUV OFF) for std 1% resistor series                             |
| <b>ENTER DEVICE VARIABLES</b>                                                          |        |       |              |          |                                                                                                                |
| Device                                                                                 | TFS762 |       |              |          | Selected HiperTFS device                                                                                       |
| Chosen Device                                                                          |        |       | TFS762       |          |                                                                                                                |
| ILIMIT_MIN                                                                             |        |       | 3.25         | A        | Device current limit (Minimum)                                                                                 |
| ILIMIT_TYP                                                                             |        |       | 3.50         | A        | Device current limit (Typical)                                                                                 |
| ILIMIT_MAX                                                                             |        |       | 3.75         | A        | Device current limit (Maximum)                                                                                 |
| fSMIN                                                                                  |        |       | 61500        | Hz       | Device switching frequency (Minimum)                                                                           |
| fS                                                                                     |        |       | 66000        | Hz       | Device switching frequency (Typical)                                                                           |



|                                       |                      |       |        |                   |                                                                                     |
|---------------------------------------|----------------------|-------|--------|-------------------|-------------------------------------------------------------------------------------|
| fSMAX                                 |                      |       | 70500  | Hz                | Device switching frequency (Maximum)                                                |
| KI                                    | 1.0                  |       | 1.0    |                   | Select Current limit factor (KI=1.0 for default ILIMIT, or select KI=0.8 or KI=0.6) |
| R(FB)                                 |                      |       | 232.0  | k-ohms            | Feedback Pin Resistor value                                                         |
| ILIMIT SELECT                         |                      |       | 3.25   | A                 | Selected current limit                                                              |
| RDS(ON)                               |                      |       | 3.05   | ohms              | Rds(on) at 100°C                                                                    |
| DVNOM_GOAL                            | 0.448                |       | 0.45   |                   | Target duty cycle at nominal input voltage (VNOM)                                   |
| VDS                                   |                      |       | 5.28   | V                 | HiperTFS average on-state Drain to Source Voltage                                   |
| <b>Clamp Selection</b>                | <b>CLAMP TO RAIL</b> |       |        |                   | Select either "CLAMP TO RAIL" (default) or "CLAMP TO GND"                           |
| VCLAMP                                | 150.00               |       | 150.00 | V                 | Asymmetric Clamp Voltage                                                            |
| VDSOP                                 |                      |       | 570.00 | V                 | Maximum HiperTFS Drain voltage (at VOVOFF_MAX)                                      |
| <b>DIODE Vf SELECTION</b>             |                      |       |        |                   |                                                                                     |
| VDMAIN                                |                      |       | 0.5    | V                 | Main output diodes forward voltage drop                                             |
| VDOUT2                                |                      |       | 0.5    | V                 | Secondary output diodes forward voltage drop                                        |
| VDOUT3                                |                      |       | 0.5    | V                 | 3rd output diodes forward voltage drop                                              |
| VDB                                   |                      |       | 0.7    | V                 | Bias diode forward voltage drop                                                     |
| <b>TRANSFORMER CORE SELECTION</b>     |                      |       |        |                   |                                                                                     |
| <b>Core Type</b>                      | <b>EER35</b>         |       |        |                   | Selected core type                                                                  |
| <i>Core</i>                           |                      | EER35 |        | P/N:              | PC40EER35-Z                                                                         |
| <i>Bobbin</i>                         |                      | EER35 | BOBBIN | P/N:              | BEER-35-1116CPH                                                                     |
| AE                                    |                      |       | 1.07   | cm <sup>2</sup>   | Core Effective Cross Sectional Area                                                 |
| LE                                    |                      |       | 9.08   | cm                | Core Effective Path Length                                                          |
| AL                                    |                      |       | 2770   | nH/T <sup>2</sup> | Ungapped Core Effective Inductance                                                  |
| BW                                    |                      |       | 26.1   | mm                | Bobbin Physical Winding Width                                                       |
| M                                     |                      |       | 4.5    | mm                | Bobbin safety margin tape width (2 * M = Total Margin)                              |
| LG MAX                                |                      |       | 0.002  | mm                | Maximum zero gap tolerance, default 2um                                             |
| L                                     |                      |       | 3.00   |                   | Transformer primary layers (split primary recommended)                              |
| NMAIN                                 |                      |       | 7.0    |                   | Main rounded turns                                                                  |
| NS2                                   |                      |       | 0.0    |                   | Vout2 rounded secondary turns (Independent windings)                                |
| NBIAS                                 |                      |       | 5      |                   | VBias rounded turns (forward bias winding)                                          |
| VOUT2 ACTUAL                          |                      |       | 0.0    | V                 | Approximate Output2 voltage of with NS2 = 0 turns (AC stacked secondary)            |
| VBIAS_ACTUAL                          |                      |       | 16.3   | V                 | Approximate Forward Bias Winding Voltage at VMIN with NB = 5 turns                  |
| <b>TRANSFORMER DESIGN PARAMETERS</b>  |                      |       |        |                   |                                                                                     |
| NP                                    |                      |       | 88     |                   | Primary rounded turns                                                               |
| BM_MAX                                |                      |       | 1791   | Gauss             | Max positive operating flux density at minimum switching frequency                  |
| BM PK-PK                              |                      |       | 2714   | Gauss             | Max peak-peak operating flux density at minimum switching frequency                 |
| BP_MAX                                |                      |       | 2321   | Gauss             | Max positive flux density at Vmax (limited by DVMAX clamp)                          |
| BP PK-PK                              |                      |       | 3516   | Gauss             | Max peak-peak flux density at Vmax (limited by DVMAX clamp)                         |
| LP MIN                                |                      |       | 20.60  | mHenries          | Minimum primary magnetizing inductance (assumes LG MAX=2um)                         |
| IMAG                                  |                      |       | 0.123  | A                 | Peak magnetizing current at minimum input voltage                                   |
| OD_P                                  |                      |       | 0.58   | mm                | Primary wire outer diameter                                                         |
| AWG_P                                 |                      |       | 23     | AWG               | Primary Wire Gauge (rounded to maximum AWG value)                                   |
| <b>DUTY CYCLE VALUES (REGULATION)</b> |                      |       |        |                   |                                                                                     |
| DVMIN                                 |                      |       | 0.57   |                   | Duty cycle at minimum DC input voltage                                              |
| DVNOM                                 |                      |       | 0.45   |                   | Duty cycle at nominal DC input voltage                                              |
| DVMAX                                 |                      |       | 0.40   |                   | Duty cycle at maximum DC input voltage                                              |



|                                                       |                  |  |                  |        |                                                                                                |
|-------------------------------------------------------|------------------|--|------------------|--------|------------------------------------------------------------------------------------------------|
| DOVOFF_MIN                                            |                  |  | 0.25             |        | Duty cycle at over-voltage DC input voltage(DOVOFF_MIN)                                        |
| <b>MAXIMUM DUTY CYCLE VALUES</b>                      |                  |  |                  |        |                                                                                                |
| DMAX_UVOFF_MIN                                        |                  |  | 0.62             |        | Max duty cycle clamp at VUVOFF_MIN                                                             |
| DMAX_VMIN                                             |                  |  | 0.60             |        | Max duty clamp cycle at VMIN                                                                   |
| DMAX_VNOM                                             |                  |  | 0.58             |        | Max duty clamp cycle at VNOM                                                                   |
| DMAX_VMAX                                             |                  |  | 0.52             |        | Max duty clamp cycle at VMAX                                                                   |
| DMAX_OVOFFMIN                                         |                  |  | 0.33             |        | Max duty clamp cycle at VOVOFF_MAX                                                             |
| <b>CURRENT WAVESHAPES PARAMETERS</b>                  |                  |  |                  |        |                                                                                                |
| IP                                                    |                  |  | 2.39             | A      | Maximum peak primary current at maximum DC input voltage                                       |
| IP_PEAK                                               |                  |  | 2.69             | A      | Peak primary current at Peak Output Power and max DC input voltage                             |
| IPRMS(NOM)                                            |                  |  | 1.38             | A      | Nominal primary RMS current at nominal DC input voltage                                        |
| <b>OUTPUT INDUCTOR OUTPUT PARAMETERS</b>              |                  |  |                  |        |                                                                                                |
| KDI_ACTUAL                                            |                  |  | 0.27             |        | Current ripple factor of combined Main and Output2 outputs                                     |
| Core Type                                             | Pow Iron         |  | Pow Iron         |        | Select core type                                                                               |
| Core                                                  | T132-52(O.D)=33) |  | T132-52(O.D)=33) |        | Coupled Inductor - Core size                                                                   |
| AE                                                    |                  |  | 80.5             | mm^2   | Core Effective Cross Sectional Area                                                            |
| LE                                                    |                  |  | 79.6             | mm     | Core Effective Path Length                                                                     |
| AL                                                    |                  |  | 95.0             | nH/T^2 | Ungapped Core Effective Inductance                                                             |
| BW                                                    |                  |  | 55.9             | mm     | Bobbin Physical Winding Width                                                                  |
| VE                                                    |                  |  | 6410.0           | mm^3   |                                                                                                |
| <b>Powder cores (Sendust and Powdered Iron) Cores</b> |                  |  |                  |        |                                                                                                |
| MUR                                                   |                  |  | 75.0             |        | Relative permeability of material                                                              |
| H                                                     |                  |  | 64.9             | AT/cm  | Magnetic field strength                                                                        |
| MUR_RATIO                                             |                  |  | 0.48             |        | Percent of permeability as compared to permeability at H = 0 AT/cm                             |
| LMAIN_ACTUAL                                          |                  |  | 16.4             | uH     | Estimated inductance of main output at full load                                               |
| LMAIN_Obias                                           |                  |  | 34.3             | uH     | Estimated inductance of main output with 0 DC bias                                             |
| LOUT2                                                 |                  |  | 0.0              | uH     | Estimated inductance of auxilliary output at full load                                         |
| BM_IND                                                |                  |  | 2919.0           | Gauss  | DC component of flux density                                                                   |
| BAC_IND                                               |                  |  | 402.8            | Gauss  | AC component of flux density                                                                   |
| <b>Turns</b>                                          |                  |  |                  |        |                                                                                                |
| INDUCTOR TURNS MULTIPLIER                             | 2.7              |  | 2.7              |        | Multiplier factor between main number of turns in transformer and inductor (default value = 3) |
| NMAIN_INDUCTOR                                        |                  |  | 19.0             |        | Main output inductor number of turns                                                           |
| NOUT2_INDUCTOR                                        |                  |  | 0.0              |        | Output 2 inductor number of turns                                                              |
| NOUT4_INDUCTOR                                        |                  |  | 12.0             |        | Bias output inductor number of turns (for bias or control circuit VDD supply)                  |
| <b>Ferrite Cores</b>                                  |                  |  |                  |        |                                                                                                |
| LMAIN_ACTUAL                                          |                  |  | N/A              | uH     | Estimated inductance of main output                                                            |
| LOUT2                                                 |                  |  | N/A              | uH     | Estimated inductance of aux output                                                             |
| LG                                                    |                  |  | N/A              | mm     | Gap length of inductor cores                                                                   |
| Target BM                                             |                  |  | N/A              | Gauss  | Target maximum flux density                                                                    |
| BM_IND                                                |                  |  | N/A              | Gauss  | Estimated maximum operating flux density                                                       |
| BAC_IND                                               |                  |  | N/A              | Gauss  | AC flux density                                                                                |
| <b>Turns</b>                                          |                  |  |                  |        |                                                                                                |
| NMAIN_INDUCUTOR                                       |                  |  | N/A              |        | Main output inductor number of turns                                                           |
| NAUX_INDUCTOR                                         |                  |  | N/A              |        | Aux output inductor number of turns                                                            |
| N_BIAS                                                |                  |  | N/A              |        | Aux output inductor number of turns                                                            |
| <b>Wire Parameters</b>                                |                  |  |                  |        |                                                                                                |
| Total number of layers                                |                  |  | 1.06             |        | Total number of layers for chosen toroid                                                       |
| IRMS_MAIN                                             |                  |  | 25.0             | A      | RMS current through main inductor windings                                                     |
| IRMS_AUX                                              |                  |  | 0.0              | A      | RMS current through aux winding                                                                |
| AWG_MAIN                                              |                  |  | 15.0             | AWG    | Main inductor winidng wire gauge                                                               |
| OD_MAIN                                               |                  |  | 1.5              | mm     | Main winding wire gauge outer diameter                                                         |



|                                                 |            |      |       |        |                                                                                |
|-------------------------------------------------|------------|------|-------|--------|--------------------------------------------------------------------------------|
| FILAR_MAIN                                      |            |      | 2.0   |        | Number of parallel strands for main output                                     |
| RDC_MAIN                                        |            |      | 4.3   | mohm   | Resistance of wire for main inductor winding                                   |
| AC Resistance Ratio (Main)                      |            |      | 4.0   |        | Ratio of total resistance (AC + DC) to the DC resistance (using Dowell curves) |
| CMA_MAIN                                        |            |      | 260.5 | CMA    | Cir mils per amp for main inductor winding                                     |
| J_MAIN                                          |            |      | 13.6  | A/mm^2 | Current density in main inductor winding                                       |
| AWG_AUX                                         |            |      | 0.0   | AWG    | Aux winding wire gauge                                                         |
| OD_MAIN                                         |            |      | N/A   | mm     | Auxiliary winding wire gauge outer diameter                                    |
| FILAR_AUX                                       |            |      | 2.0   |        | Number of parallel strands for aux output                                      |
| RDC_AUX                                         |            |      | 0.0   | mohm   | Resistance of wire for aux inductor winding                                    |
| AC Resistance Ratio (Aux)                       |            |      | 0.00  |        | Ratio of total resistance (AC + DC) to the DC resistance (using Dowell curves) |
| CMA_AUX                                         |            | Info | 0.0   | CMA    | !!! Info. Low CMA may cause overheating. Verify acceptable temperature rise    |
| J_AUX                                           |            |      | 0.0   | A/mm^2 | Current density in auxiliary winding                                           |
| <b>Estimated Power Loss</b>                     |            |      |       |        |                                                                                |
| PCOPPER_MAIN                                    |            |      | 2.7   | W      | Copper loss in main inductor winding                                           |
| PCOPPER_AUX                                     |            |      | 0.0   | W      | Copper loss in aux inductor windings                                           |
| PCORE                                           |            |      | 2.2   | W      | Total core loss                                                                |
| PTOTAL                                          |            |      | 4.9   | W      | Total losses in output choke                                                   |
| <b>SECONDARY OUTPUT PARAMETERS</b>              |            |      |       |        |                                                                                |
| ISFWRMS                                         |            |      | 18.99 | A      | Max. fwd sec. RMS current (at DVNOM)                                           |
| ISFWD2RMS                                       |            |      | 0.00  | A      | Max. fwd sec. RMS current (at DVNOM)                                           |
| ISCATCHRMS                                      |            |      | 21.16 | A      | Max. catch sec. RMS current (at DVNOM)                                         |
| ISCATCH2RMS                                     |            |      | 0.00  | A      | Max. catch sec. RMS current (at DVNOM)                                         |
| IDAVMAINF                                       |            |      | 14.18 | A      | Maximum average current, Main rectifier (single device rating)                 |
| IDAVMAINC                                       |            |      | 14.92 | A      | Maximum average current, Main rectifier (single device rating)                 |
| IDAVOUT2F                                       |            |      | 0.00  | A      | Maximum average current, Main rectifier (single device rating)                 |
| IDAVOUT2C                                       |            |      | 0.00  | A      | Maximum average current, Main rectifier (single device rating)                 |
| IRMSMAIN                                        |            |      | 1.98  | A      | Maximum RMS current, Main output capacitor                                     |
| IRMSOUT2                                        |            |      | 0.00  | A      | Maximum RMS current, Out2 output capacitor                                     |
|                                                 | % Derating |      |       |        |                                                                                |
| VPIVMAINF                                       | 100%       |      | 45.3  | V      | Main Forward Diode peak-inverse voltage (at VDSOP)                             |
| VPIVMAINC                                       | 100%       |      | 33.4  | V      | Main Catch Diode peak-inverse voltage (at VOVOFF_MAX)                          |
| VPIVOUT2F                                       | 100%       |      | 0.0   | V      | Output2 Forward Diode peak-inverse voltage (at VDSOP)                          |
| VPIVOUT2C                                       | 100%       |      | 0.0   | V      | Output2 Catch Diode peak-inverse voltage (at VOVOFF_MAX)                       |
| VPIVB                                           | 100%       |      | 32.4  | V      | Bias output rectifier peak-inverse voltage (at VDSOP)                          |
| <b>HiperTFS STANDBY SECTION (FLYBACK STAGE)</b> |            |      |       |        |                                                                                |
| <b>ENTER APPLICATION VARIABLES</b>              |            |      |       |        |                                                                                |
| VACMIN                                          | 85         |      |       | V      | Minimum AC Input Voltage                                                       |
| VACMAX                                          | 265        |      |       | V      | Maximum AC Input Voltage                                                       |
| fL                                              | 50         |      |       | Hz     | AC Mains Frequency                                                             |
| VO_SB                                           | 5.00       |      |       | V      | Output Voltage (at continuous power)                                           |
| IO_SB                                           | 2.00       |      |       | A      | Power Supply Output Current (corresponding to peak power)                      |
| IO_SB_PK                                        | 2.90       |      |       |        |                                                                                |
| POUT_SB                                         |            |      | 10    | W      | Continuous Output Power                                                        |
| POUT_SB_TOTAL                                   |            |      | 10.32 | W      | Total Standby power (Includes Bias winding power)                              |
| POUT_SB_PK                                      |            |      | 14.7  | W      | Peak Standby Output Power                                                      |



|                                                      |       |      |                        |                    |                                                                                                                                                                                                 |
|------------------------------------------------------|-------|------|------------------------|--------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| n                                                    | 0.70  |      |                        |                    | Efficiency Estimate at output terminals. Under 0.7 if no better data available                                                                                                                  |
| Z                                                    | 0.50  |      |                        |                    | Z Factor. Ratio of secondary side losses to the total losses in the power supply. Use 0.5 if no better data available                                                                           |
| tC                                                   | 3.00  |      |                        | ms                 | Bridge Rectifier Conduction Time Estimate                                                                                                                                                       |
| <b>ENTER HiperTFS STANDBY VARIABLES</b>              |       |      |                        |                    |                                                                                                                                                                                                 |
| Select Current Limit                                 | STD   |      | Standard Current Limit |                    | Enter "LOW" for low current limit, "RED" for reduced current limit (sealed adapters), "STD" for standard current limit or "INC" for increased current limit (peak or higher power applications) |
| ILIM_MIN                                             |       |      | 0.605                  | A                  | Minimum Current Limit                                                                                                                                                                           |
| ILIM_TYP                                             |       |      | 0.650                  | A                  | Typical Current Limit                                                                                                                                                                           |
| ILIM_MAX                                             |       |      | 0.696                  | A                  | Maximum Current Limit                                                                                                                                                                           |
| R(EN)                                                |       |      | 280.0                  | k-ohms             | Enable pin resistor                                                                                                                                                                             |
| fSmin                                                |       |      | 124000                 | Hz                 | Minimum Device Switching Frequency                                                                                                                                                              |
| I <sup>2</sup> fmin                                  |       |      | 50.19                  | A <sup>2</sup> kHz | I <sup>2</sup> f (product of current limit squared and frequency is trimmed for tighter tolerance)                                                                                              |
| VOR                                                  | 90.00 |      | 90                     | V                  | Reflected Output Voltage (VOR < 135 V Recommended)                                                                                                                                              |
| VDS                                                  |       |      | 10                     | V                  | HiperTFS Standby On State Drain to Source Voltage                                                                                                                                               |
| VD_SB                                                |       |      | 0.5                    | V                  | Output Winding Diode Forward Voltage Drop                                                                                                                                                       |
| KP                                                   |       |      | 0.71                   |                    | Ripple to Peak Current Ratio (KP < 6)                                                                                                                                                           |
| KP_TRANSIENT                                         |       |      | 0.36                   |                    | Transient Ripple to Peak Current Ratio. Ensure KP_TRANSIENT > 0.25                                                                                                                              |
| <b>ENTER BIAS WINDING VARIABLES</b>                  |       |      |                        |                    |                                                                                                                                                                                                 |
| VB                                                   |       |      | 16.00                  | V                  | Bias Winding Voltage                                                                                                                                                                            |
| IB                                                   |       |      | 20.00                  | mA                 | Bias winding Load current                                                                                                                                                                       |
| PB                                                   |       |      | 0.32                   | W                  | Bias winding power                                                                                                                                                                              |
| VDB                                                  |       |      | 0.70                   | V                  | Bias Winding Diode Forward Voltage Drop                                                                                                                                                         |
| NB                                                   |       |      | 9.11                   |                    | Bias Winding Number of Turns                                                                                                                                                                    |
| VZOV                                                 |       |      | 22.00                  | V                  | Over Voltage Protection zener diode voltage.                                                                                                                                                    |
| <b>UVLO VARIABLES</b>                                |       |      |                        |                    |                                                                                                                                                                                                 |
| RLS                                                  |       |      | 4.00                   | M-Ohms             | Line sense resistor (from Main converter section)                                                                                                                                               |
| V_UV_ACTUAL                                          |       |      | 102                    | V                  | Typical DC start-up voltage                                                                                                                                                                     |
| <b>ENTER TRANSFORMER CORE/CONSTRUCTION VARIABLES</b> |       |      |                        |                    |                                                                                                                                                                                                 |
| Core Type                                            | EE25  |      | EE25                   |                    | Enter Transformer Core                                                                                                                                                                          |
| Core                                                 |       | EE25 |                        | P/N:               | PC40EE25-Z                                                                                                                                                                                      |
| Bobbin                                               |       | EE25 | BOBBIN                 | P/N:               | EE25_BOBBIN                                                                                                                                                                                     |
| AE                                                   |       |      | 0.404                  | cm <sup>2</sup>    | Core Effective Cross Sectional Area                                                                                                                                                             |
| LE                                                   |       |      | 7.34                   | cm                 | Core Effective Path Length                                                                                                                                                                      |
| AL                                                   |       |      | 1420                   | nH/T <sup>2</sup>  | Ungapped Core Effective Inductance                                                                                                                                                              |
| BW                                                   |       |      | 10.2                   | mm                 | Bobbin Physical Winding Width                                                                                                                                                                   |
| M                                                    |       |      | 0                      | mm                 | Safety Margin Width (Half the Primary to Secondary Creepage Distance)                                                                                                                           |
| L                                                    |       |      | 2                      |                    | Number of Primary Layers                                                                                                                                                                        |
| NS_SB                                                |       |      | 3                      |                    | Number of Secondary Turns                                                                                                                                                                       |
| <b>DC INPUT VOLTAGE PARAMETERS</b>                   |       |      |                        |                    |                                                                                                                                                                                                 |
| VMIN_SB                                              |       |      | 115.65                 | V                  | Minimum DC Input Voltage                                                                                                                                                                        |
| VMAX_SB                                              |       |      | 374.77                 | V                  | Maximum DC Input Voltage                                                                                                                                                                        |
| <b>CURRENT WAVEFORM SHAPE PARAMETERS</b>             |       |      |                        |                    |                                                                                                                                                                                                 |
| DMAX_SB                                              |       |      | 0.46                   |                    | Duty Ratio at full load, minimum primary inductance and minimum input voltage                                                                                                                   |
| IAVG                                                 |       |      | 0.20                   | A                  | Average Primary Current                                                                                                                                                                         |
| IP_SB                                                |       |      | 0.60                   | A                  | Minimum Peak Primary Current                                                                                                                                                                    |
| IR_SB                                                |       |      | 0.43                   | A                  | Primary Ripple Current                                                                                                                                                                          |
| IRMS_SB                                              |       |      | 0.32                   | A                  | Primary RMS Current                                                                                                                                                                             |
| <b>TRANSFORMER PRIMARY DESIGN PARAMETERS</b>         |       |      |                        |                    |                                                                                                                                                                                                 |
| LP_SB                                                |       |      | 841.65                 | uH                 | Typical Primary Inductance. +/- 10% to ensure a minimum primary inductance of 765 uH                                                                                                            |



|                                                |  |      |      |           |                                                                                                                |
|------------------------------------------------|--|------|------|-----------|----------------------------------------------------------------------------------------------------------------|
| LP_TOLERANCE                                   |  |      | 10   | %         | Primary inductance tolerance                                                                                   |
| NP_SB                                          |  |      | 49   |           | Primary Winding Number of Turns                                                                                |
| ALG                                            |  |      | 349  | nH/T^2    | Gapped Core Effective Inductance                                                                               |
| BM                                             |  |      | 2952 | Gauss     | Maximum Operating Flux Density, BM<3000 is recommended                                                         |
| BAC                                            |  |      | 1050 | Gauss     | AC Flux Density for Core Loss Curves (0.5 X Peak to Peak)                                                      |
| ur                                             |  |      | 2053 |           | Relative Permeability of Ungapped Core                                                                         |
| LG                                             |  |      | 0.11 | mm        | Gap Length (Lg > 0.1 mm)                                                                                       |
| BWE                                            |  |      | 20.4 | mm        | Effective Bobbin Width                                                                                         |
| OD                                             |  |      | 0.42 | mm        | Maximum Primary Wire Diameter including insulation                                                             |
| INS                                            |  |      | 0.06 | mm        | Estimated Total Insulation Thickness (= 2 * film thickness)                                                    |
| DIA                                            |  |      | 0.35 | mm        | Bare conductor diameter                                                                                        |
| AWG                                            |  |      | 28   | AWG       | Primary Wire Gauge (Rounded to next smaller standard AWG value)                                                |
| CM                                             |  |      | 161  | Cmils     | Bare conductor effective area in circular mils                                                                 |
| CMA                                            |  | Info | 506  | Cmils/Amp | CAN DECREASE CMA < 500 (decrease L(primary layers),increase NS,use smaller Core)                               |
| <b>TRANSFORMER SECONDARY DESIGN PARAMETERS</b> |  |      |      |           |                                                                                                                |
| <b>Lumped parameters</b>                       |  |      |      |           |                                                                                                                |
| ISP                                            |  |      | 9.89 | A         | Peak Secondary Current                                                                                         |
| ISRMS                                          |  |      | 5.65 | A         | Secondary RMS Current                                                                                          |
| IRIPPLE                                        |  |      | 5.29 | A         | Output Capacitor RMS Ripple Current                                                                            |
| CMS                                            |  |      | 1131 | Cmils     | Secondary Bare Conductor minimum circular mils                                                                 |
| AWGS                                           |  |      | 19   | AWG       | Secondary Wire Gauge (Rounded up to next larger standard AWG value)                                            |
| <b>VOLTAGE STRESS PARAMETERS</b>               |  |      |      |           |                                                                                                                |
| VDRAIN                                         |  |      | 584  | V         | Maximum Drain Voltage Estimate (Assumes 20% zener clamp tolerance and an additional 10% temperature tolerance) |
| PIVS                                           |  |      | 28   | V         | Output Rectifier Maximum Peak Inverse Voltage                                                                  |



## 11 Performance Data

All measurements are performed at the PCB connector at room temperature and 380 VDC input. For standby measurements, DC input voltage was adjusted to match the equivalent AC voltage.

### 11.1 Main and Standby Efficiency

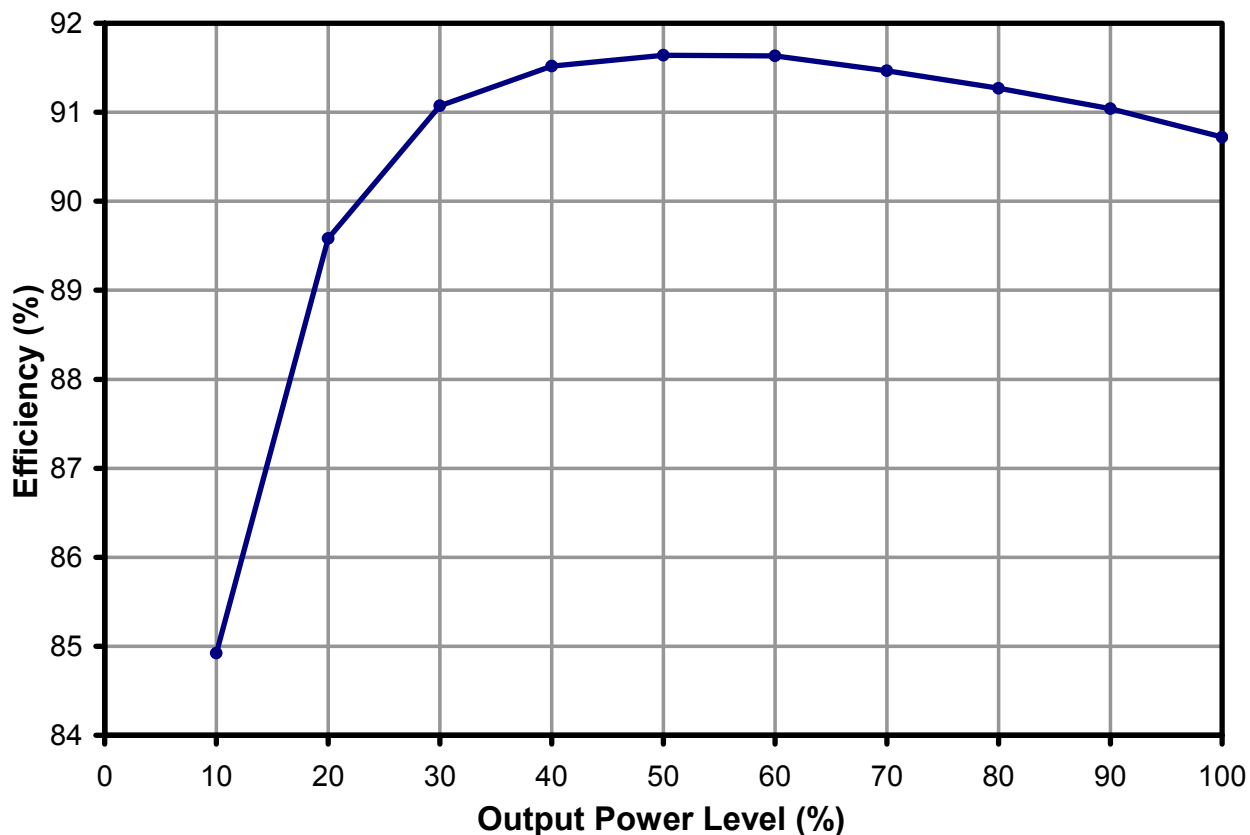
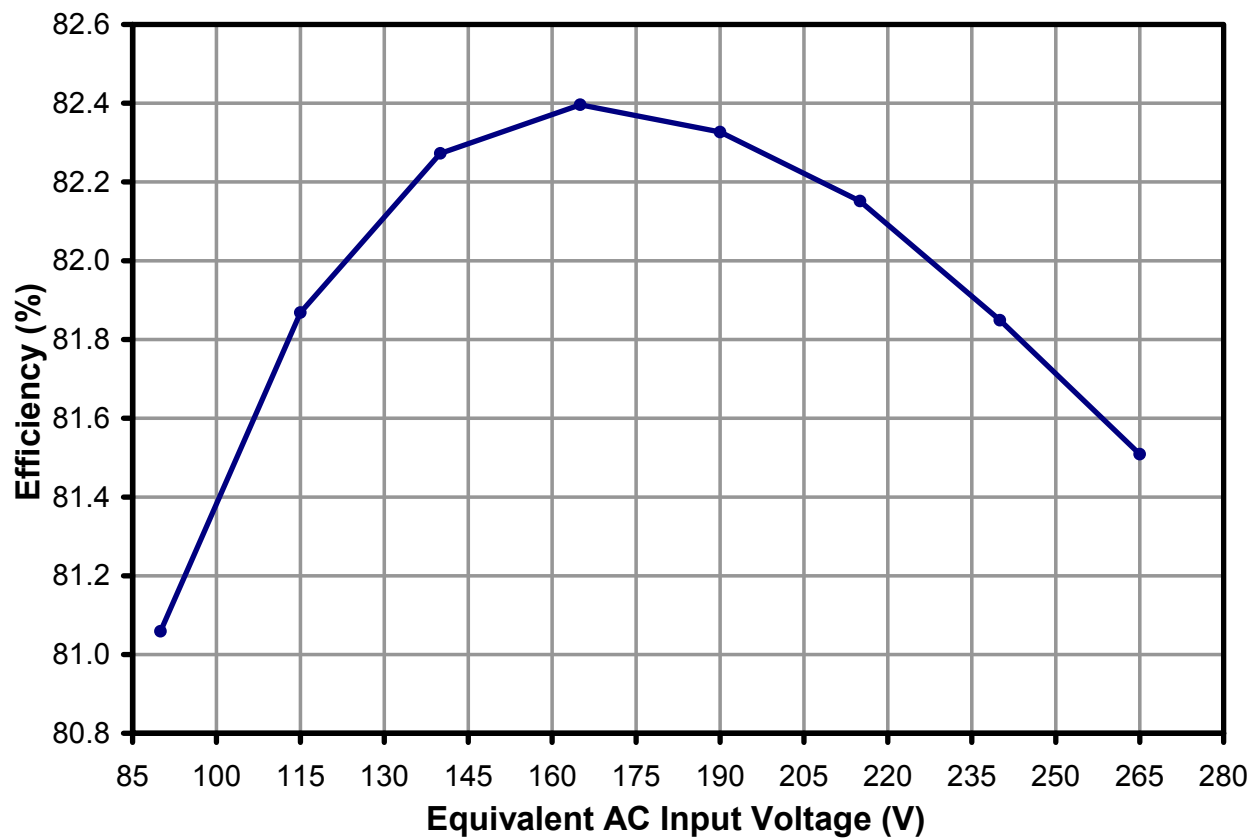


Figure 11 – Main and Standby Efficiency [%], Room Temperature, Forced Cooling.



**11.2 Full Power Standby Efficiency vs. Equivalent AC Input Voltage**

**Figure 12 – Full Power Standby Efficiency [%] vs. AC Input Voltage [V] at Room Temperature**



### 11.3 Standby Efficiency vs. Output Power

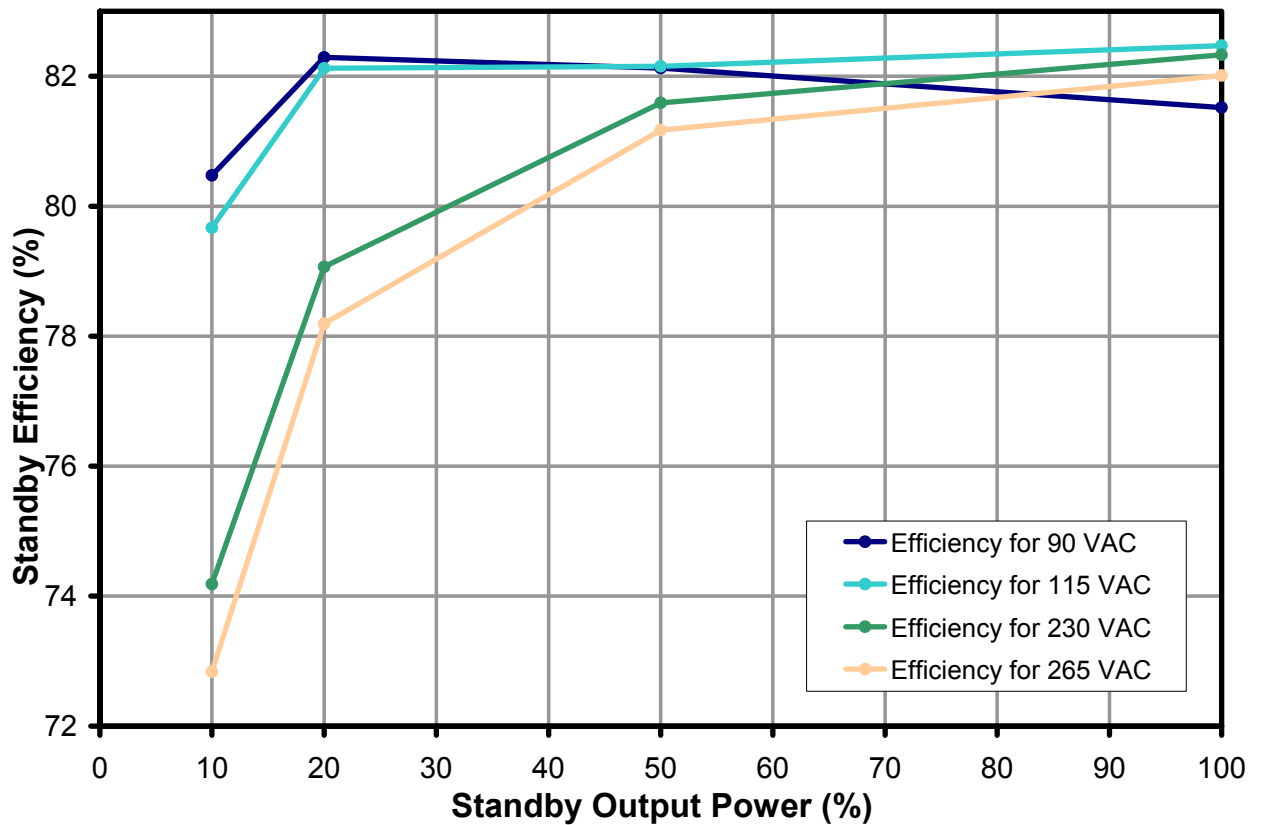
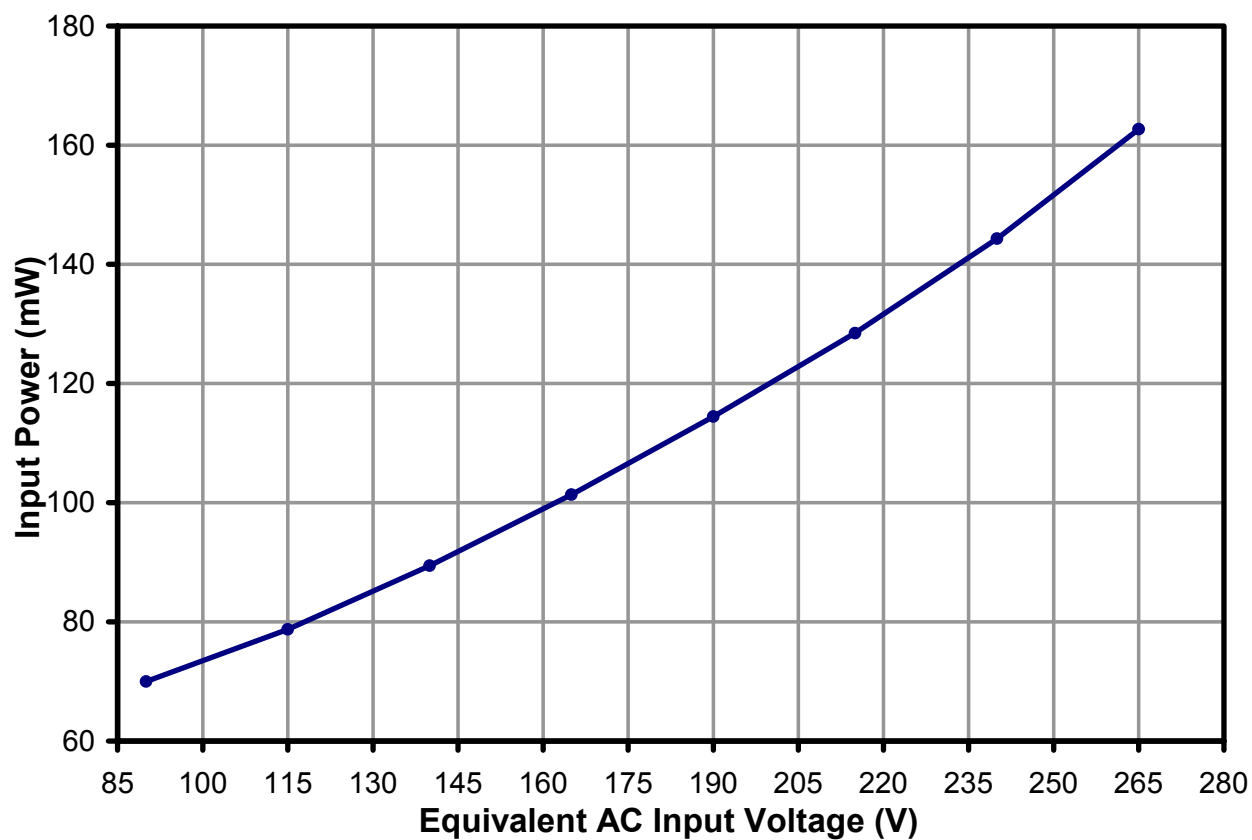


Figure 13 – Standby Efficiency [%], at Room Temperature and Equivalent AC Input Voltage.

#### 11.4 Standby Only No-Load Input Power



**Figure 14** – Input Power [mW] vs. Input Line Voltage [V], for Zero Standby Load at Room Temperature.



## 11.5 Main and Standby Voltage Regulation

### 11.5.1 Main Load Regulation

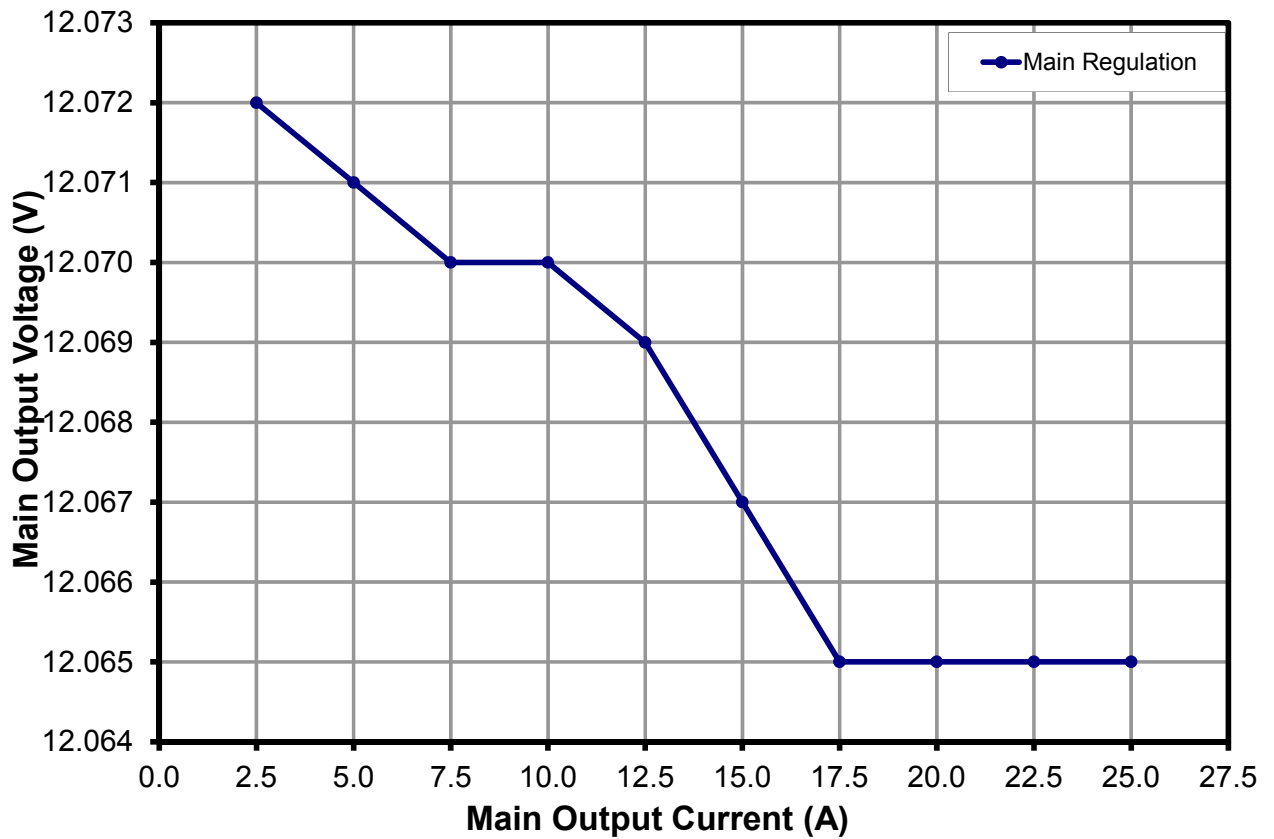


Figure 15 – Main Load Regulation, at Room Temperature and 380 VDC Input Voltage.

## 11.5.2 Standby Load Regulation at Equivalent AC Input Voltages

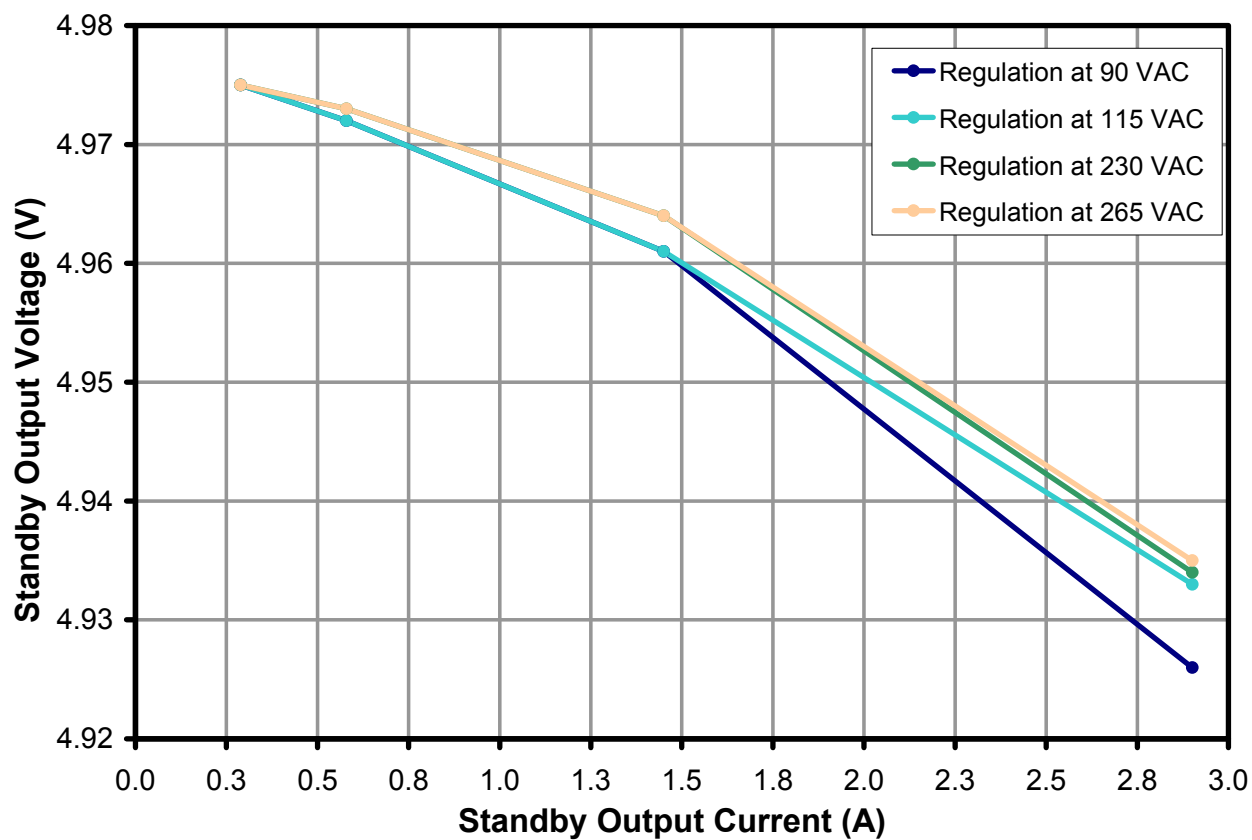
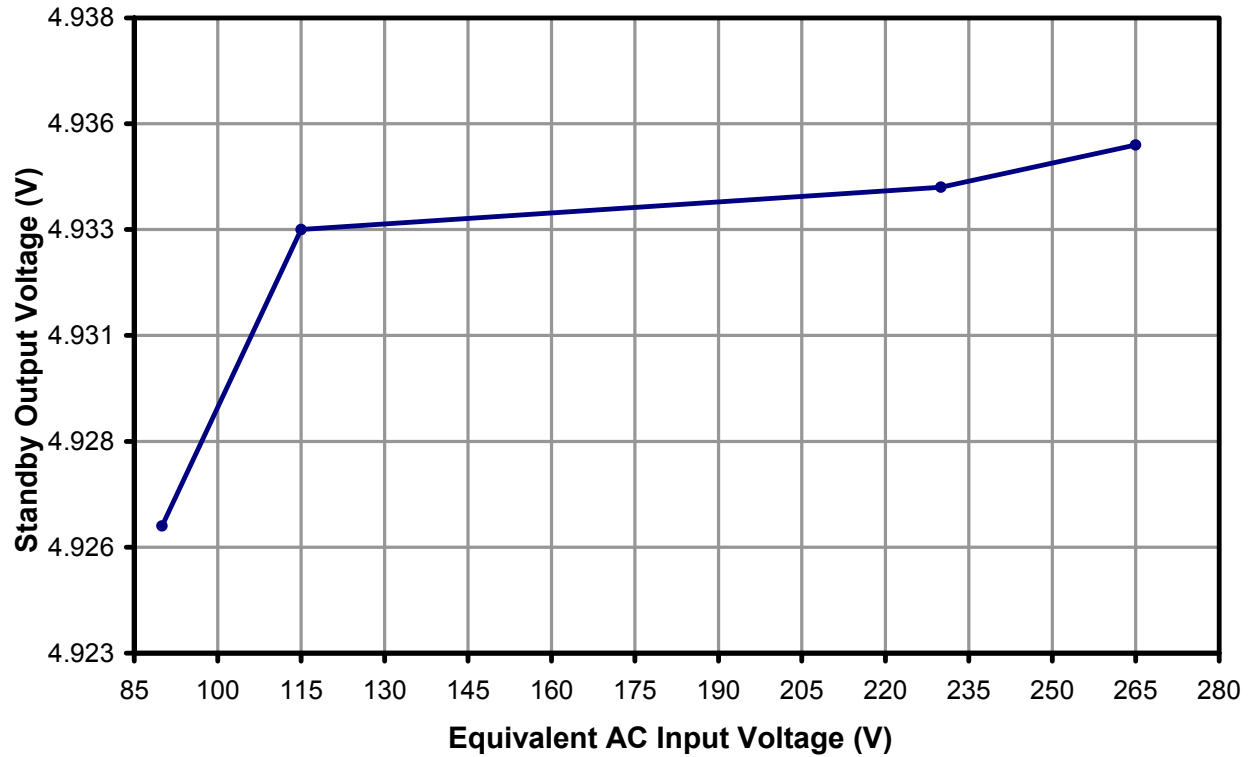


Figure 16 – Standby Load Regulation, at Room Temperature and Equivalent AC Input Voltage.



## 11.5.3 Standby Line Regulation at Full Power



**Figure 17** – Line Regulation, at Room Temperature, Full Load.



## 12 Thermal Performance

Full output power operation at room temperature is allowed only for operation time under 10 minutes. It is required to provide forced air cooling for operation at full power for more than 10 minutes or for over-power tests.

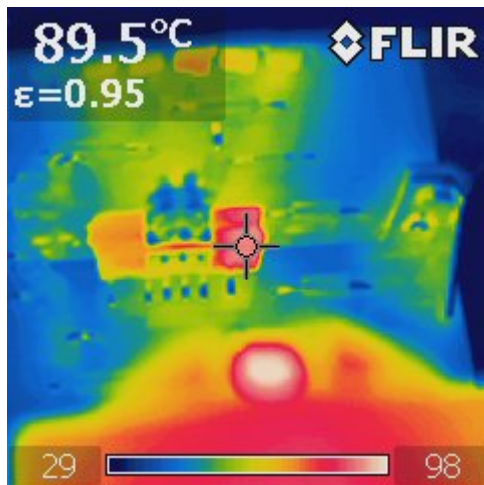


Figure 18 – HiperTFS Device Temperature.

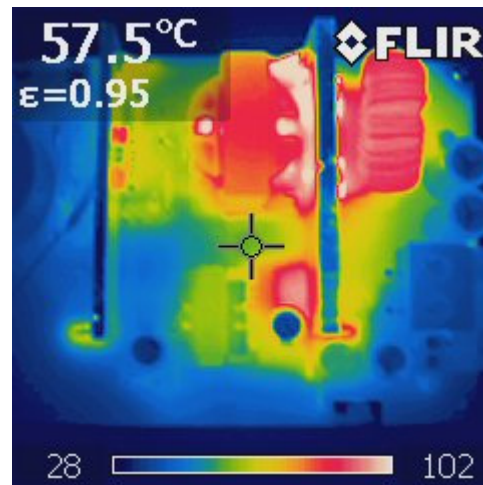
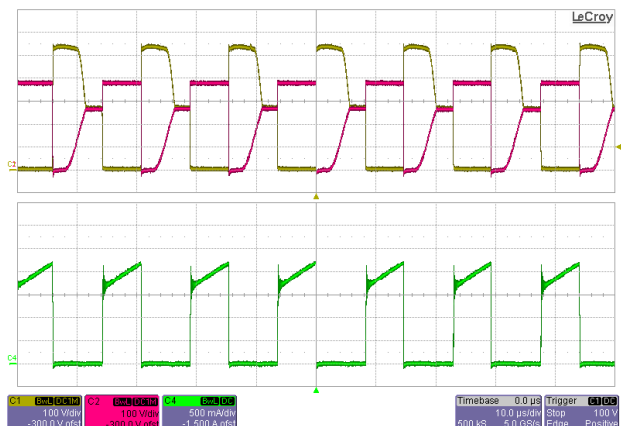


Figure 19 – Board Thermal Image.

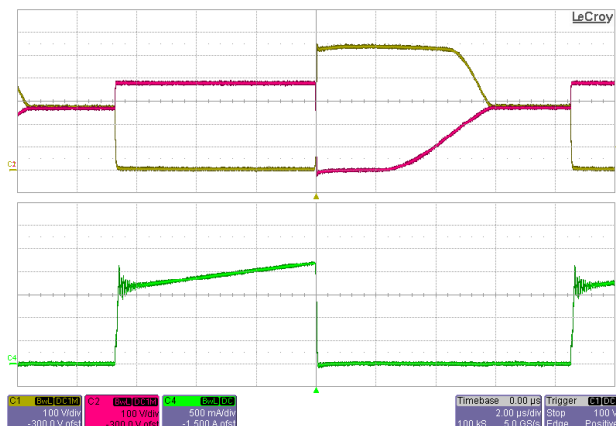
In case of power components replacement it is important to insure a clean and smooth surfaces for heat-sink mechanical assembly with thermal conductive grease between any surface in contact, even for the isolation pad.

## 13 Waveforms

### 13.1 Main Drain Voltage and Current, Normal Operation, Full Power

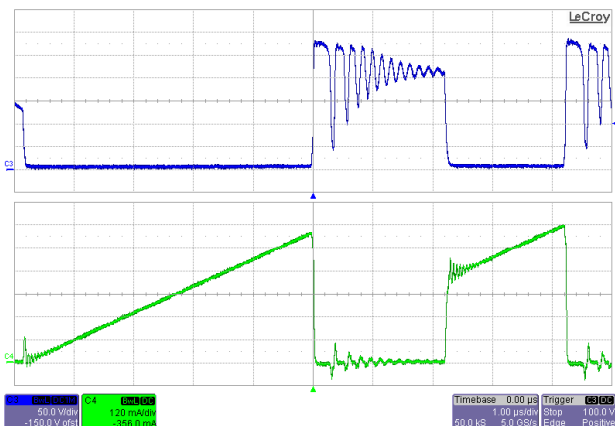


**Figure 20** – Input Voltage: 380 VDC  
 Upper: Main Upper MOSFET (Red) V<sub>SOURCE</sub>,  
 100 V / div.  
 Upper: Main Lower MOSFET (Gold) V<sub>DRAIN</sub>,  
 100 V / div.  
 Lower: Main I<sub>DRAIN</sub>, 500 mA, 10 μs / div.

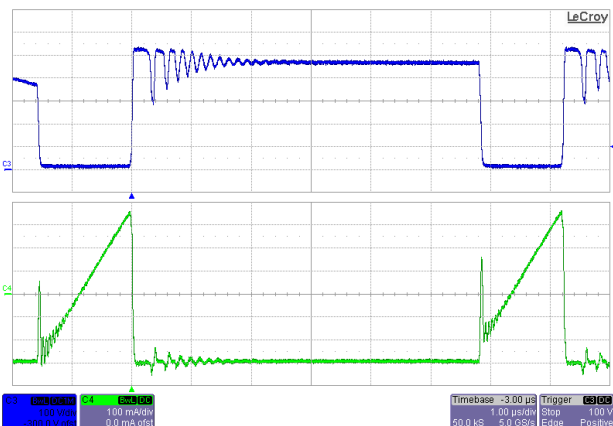


**Figure 21** – Input Voltage: 380 VDC  
 Upper: Main Upper MOSFET (Red) V<sub>SOURCE</sub>,  
 100 V / div.  
 Upper: Main Lower MOSFET (Gold) V<sub>DRAIN</sub>,  
 100 V / div.  
 Lower: Main I<sub>DRAIN</sub>, 500 mA, 2 μs / div.

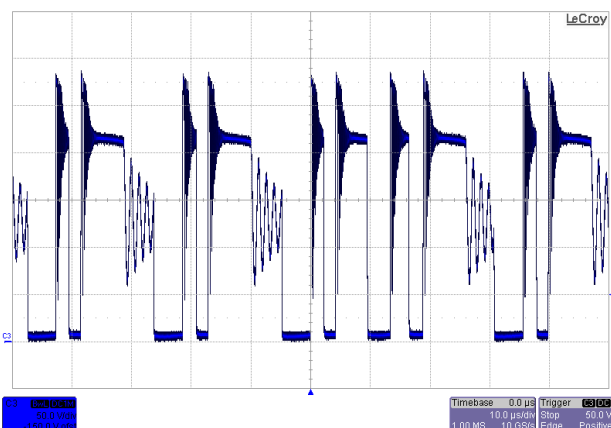
### 13.2 Standby Drain Voltage and Current, Normal Operation, Full Power



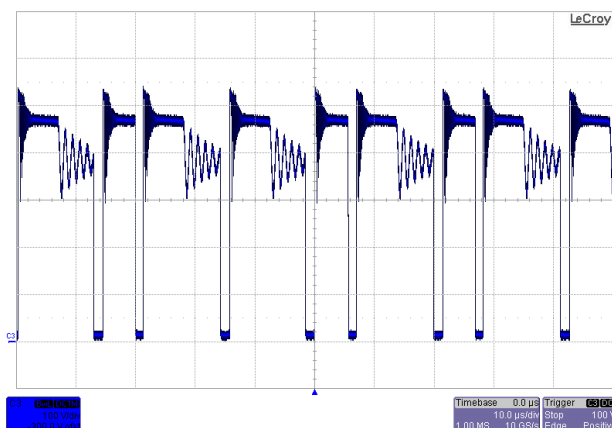
**Figure 22** – Input Voltage: 127 VDC  
Upper: Standby  $V_{DRAIN}$ , 50 V / div.  
Lower: Standby  $I_{DRAIN}$ , 120 mA, 1  $\mu$ s / div.



**Figure 23** – Input Voltage: 380 VDC  
Upper: Standby  $V_{DRAIN}$ , 100 V / div.  
Lower: Standby  $I_{DRAIN}$ , 100 mA, 1  $\mu$ s / div.

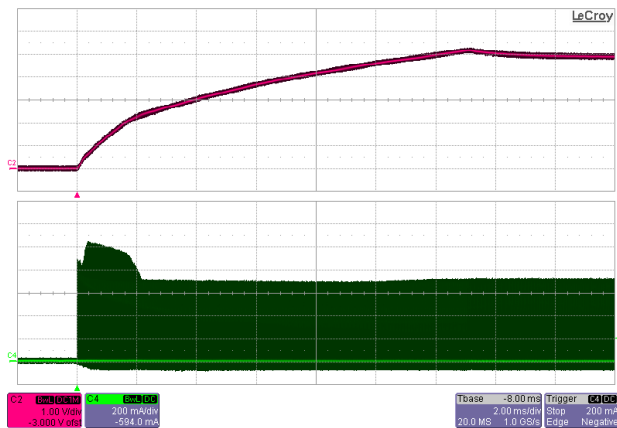


**Figure 24** – Input Voltage: 127 VDC  
Standby  $V_{DRAIN}$ , 50 V / div., 10  $\mu$ s / div.

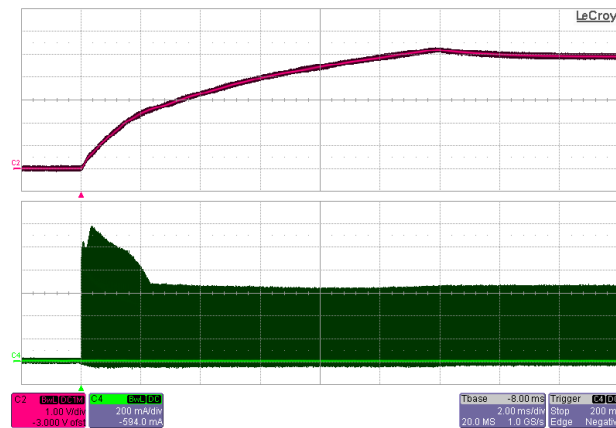


**Figure 25** – 380 VDC  
Standby  $V_{DRAIN}$ , 100 V / div., 10  $\mu$ s / div.

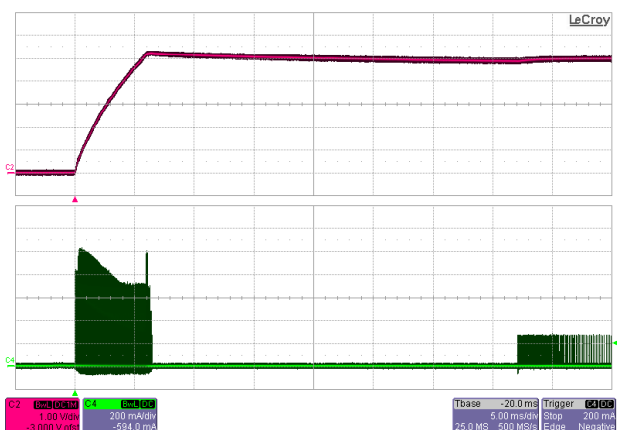
### 13.3 Standby Drain Current and Output Voltage Start-Up Profile



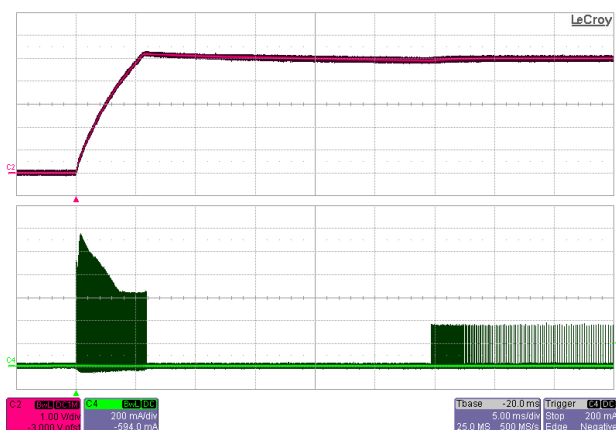
**Figure 26 – Full Load: 127 VDC Input Voltage.**  
Upper:  $V_{STBY}$ , 1 V / div.  
Lower: Standby  $I_{DRAIN}$ , 200 mA, 2 ms / div.



**Figure 27 – Full Load: 380 VDC Input Voltage.**  
Upper:  $V_{STBY}$ , 1V / div.  
Lower: Standby  $I_{DRAIN}$ , 200 mA, 2 ms / div.

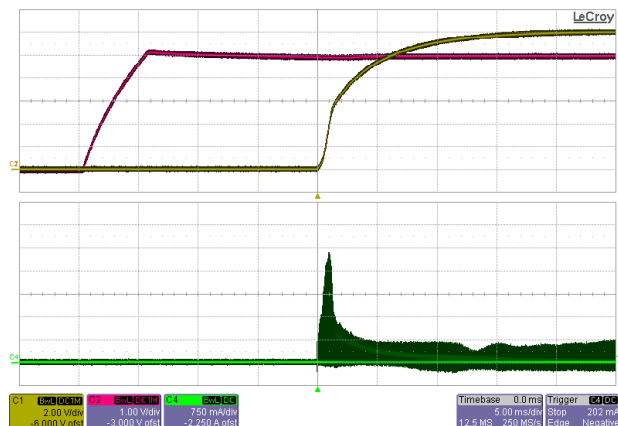


**Figure 28 – No-load at 127 VDC Input Voltage**  
Upper:  $V_{STBY}$ , 1 V / div.  
Lower: Standby  $I_{DRAIN}$ , 200 mA, 5 ms / div.



**Figure 29 – No-load at 380 VDC Input Voltage**  
Upper:  $V_{STBY}$ , 1 V / div.  
Lower: Standby  $I_{DRAIN}$ , 200 mA, 5 ms / div.

### 13.4 Main Drain Current, and Main and Standby Output Voltage Start-Up Profile



**Figure 30** – No-load: 380 VDC Input Voltage.

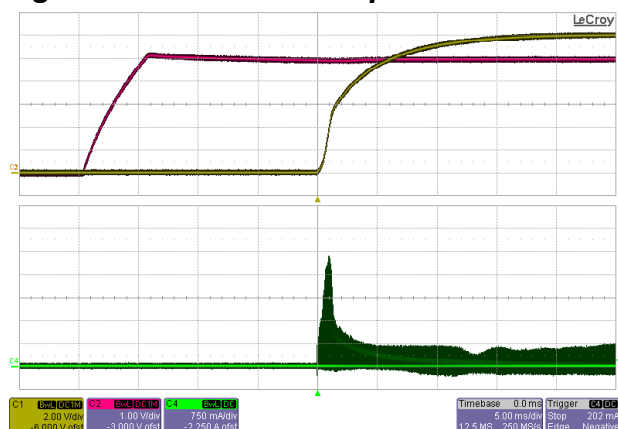
Upper (Red):  $V_{STBY}$ , 1 V / div.

Upper (Yellow):  $V_{MAIN}$ , 2 V / div.

Lower: Main  $I_{DRAIN}$ , 750 mA, 5 ms / div.

For this test the DC input voltage was applied with remote-ON/OFF switch in ON position.

### 13.5 Main Output Voltage Remote-ON Start-Up Profile



**Figure 31** – No-load: 380 VDC Input Voltage.

Upper (Red):  $V_{STBY}$ , 1 V / div.

Upper (Yellow):  $V_{MAIN}$ , 2 V / div.

Lower: Main  $I_{DRAIN}$ , 750 mA, 5 ms / div.



### 13.6 Main or Standby OV Shutdown

In order to activate the Standby or Main Overvoltage Protection Circuit for testing purpose, the recommended procedure is to temporarily short-circuit the input side of the respective optocouplers: U1A for the Main section or U2A for the Standby section. Without proper signal, the feedback loop will be forced to maximize the control signal and the Main or the Standby output voltage will increase all the way up to the shut-down limit. This overvoltage trigger condition will force the current into the BP pin to exceed the threshold limit and the internal HiperTFS controller to lock-out in a disabled state. For resetting the lock-out condition, the input voltage must be removed to allow the voltage on the BP pin to be discharged.

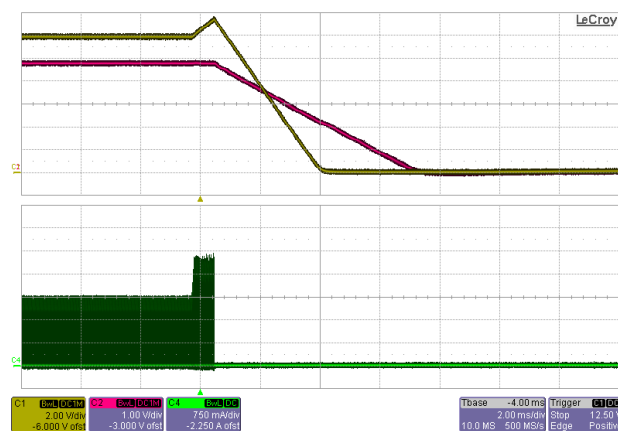


**Figure 32 – Standby OV Protection.**

Upper (Red):  $V_{STBY}$ , 1 V / div.

Upper (Yellow):  $V_{MAIN}$ , 2 V / div.

Lower: Standby  $I_{DRAIN}$ , 200 mA, 2 ms / div.



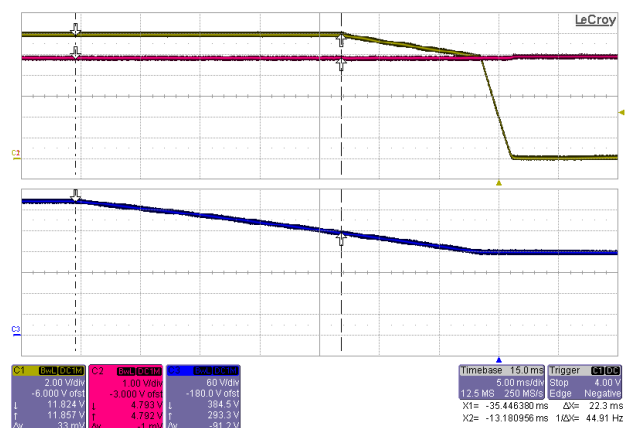
**Figure 33 – Main OV Protection.**

Upper (Red):  $V_{STBY}$ , 1 V / div.

Upper (Yellow):  $V_{MAIN}$ , 2 V / div.

Lower: Main  $I_{DRAIN}$ , 750 mA, 2 ms / div.

### 13.7 Full Power Hold-Up Time



**Figure 34** – Maximum Hold-Up Time = 22.3 ms

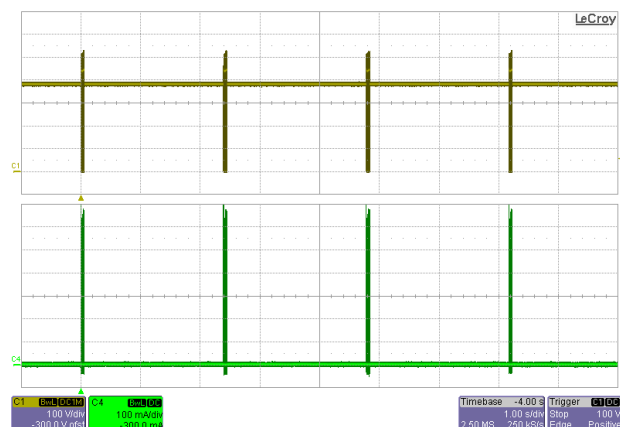
Upper (Yellow):  $V_{MAIN}$ , 2 V / div.

Upper (Red):  $V_{STBY}$ , 1 V / div.

Lower: Input VDC, 60 V, 5 ms / div.

After turning OFF the input voltage, the full output power Hold-Up Time from 385 VDC down to 300 VDC is 20.8 ms. Maximum Hold-Up time (before 12 V Main output losing regulation, starting from 385 VDC input) is 22.3 ms.

### 13.8 Standby Auto-Restart



**Figure 35** – Maximum Hold-Up Time = 22.3 ms

Upper: Standby  $V_{DRAIN}$ , 100 V / div.

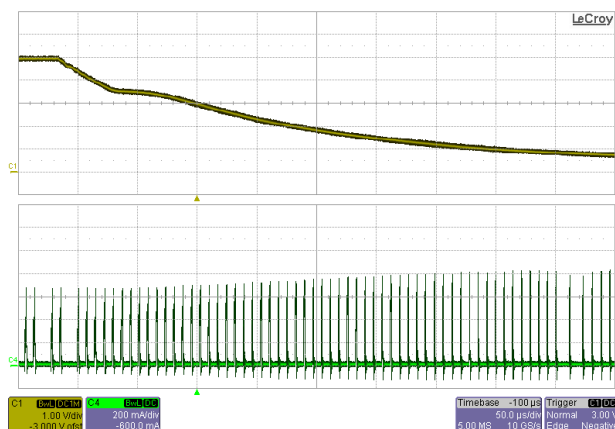
Lower: Standby  $I_{DRAIN}$ , 100 mA, 1 s / div.

Overloading the standby output with 6 A for 380 VDC input shows repeated restart attempts every 2.3 s followed by a quick shutdown.

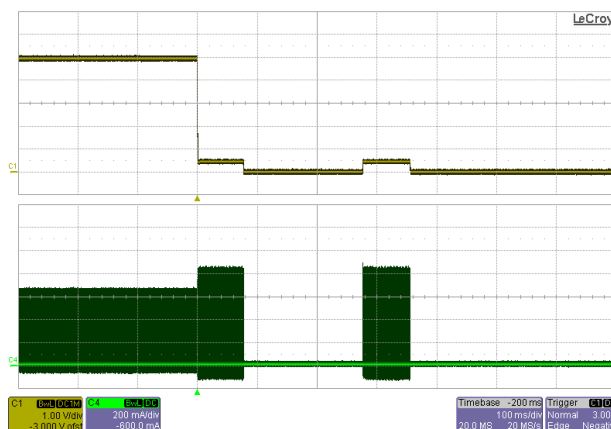


### 13.9 Main and Standby Full Power Output Short-Circuit

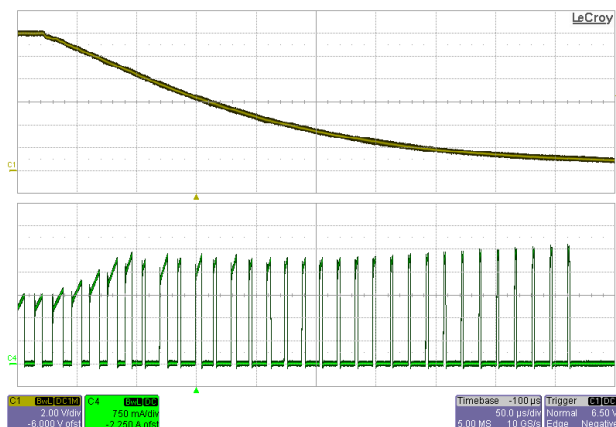
For short-circuit testing the recommended procedure is to use MOSFETs like IXYS IXFN180N25T or equivalent devices with high current capability connected to both Main and Standby outputs. In Short-Circuit mode only the output connectors and cable wires will have any significant resistivity. The unit will withstand short-circuit conditions without any permanent damage, and the outputs will go back to normal after the fault condition is removed. The Standby controller will try a restart cycle any time when the restart conditions are satisfied.



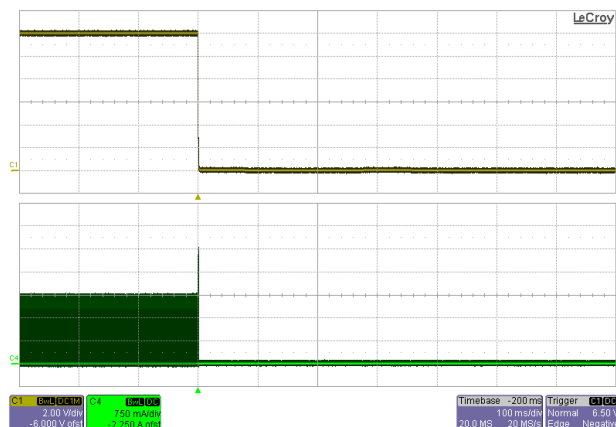
**Figure 36 – Standby Output Short-Circuit.**  
Upper:  $V_{STBY}$ , 1 V / div.  
Lower: Standby  $I_{DRAIN}$ , 200 mA, 50  $\mu$ s / div.



**Figure 37 – Standby Output Short-Circuit.**  
Upper:  $V_{STBY}$ , 1 V / div.  
Lower: Standby  $I_{DRAIN}$ , 200 mA, 100 ms / div.

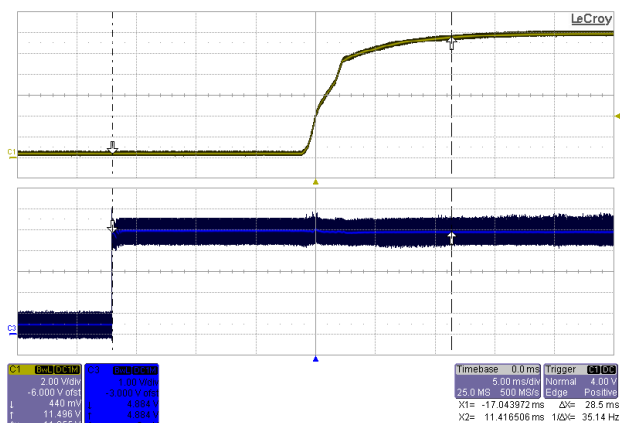


**Figure 38 – Main Output Short-Circuit.**  
Upper:  $V_{MAIN}$ , 2 V / div.  
Lower: Main  $I_{DRAIN}$ , 750 mA, 50  $\mu$ s / div.



**Figure 39 – Main Output Short-Circuit.**  
Upper:  $V_{MAIN}$ , 2 V / div.  
Lower: Main  $I_{DRAIN}$ , 750 mA, 100 ms / div.

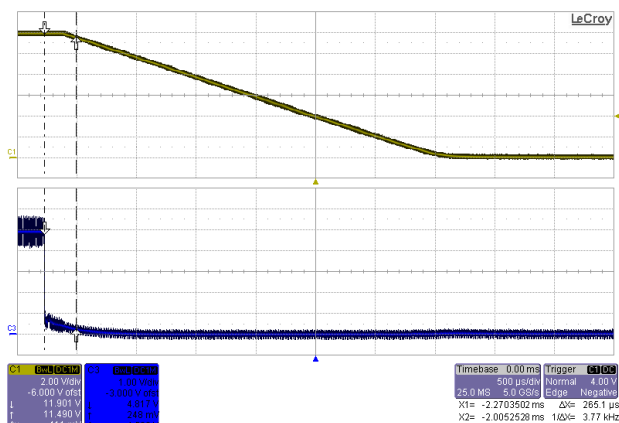
### 13.10 Main Remote-ON/OFF



**Figure 40** – Main Remote-ON: 385 VDC = 28.5 ms.

Upper:  $V_{MAIN}$ , 2 V / div.

Lower: Remote-ON, 1 V, 5 ms / div.



**Figure 41** – Main Remote-OFF: 385 VDC = 265  $\mu$ s.

Upper:  $V_{MAIN}$ , 2 V / div.

Lower: Remote-OFF, 1 V, 5 ms / div.

Main Remote-ON start-up time is measured between Remote-ON/OFF signal going in ON state and Main 12 V output reaching 11.5 V, and it is 28.5 ms. Main Remote-OFF shut-down time is measured from Remote-ON/OFF signal going in OFF state and Main 12 V output going down to 11.5 V, and it is 265  $\mu$ s.

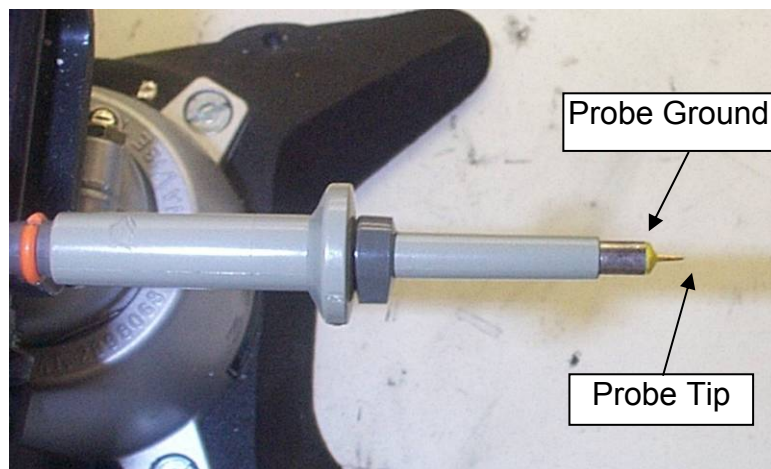


### 13.11 Output Ripple Measurements

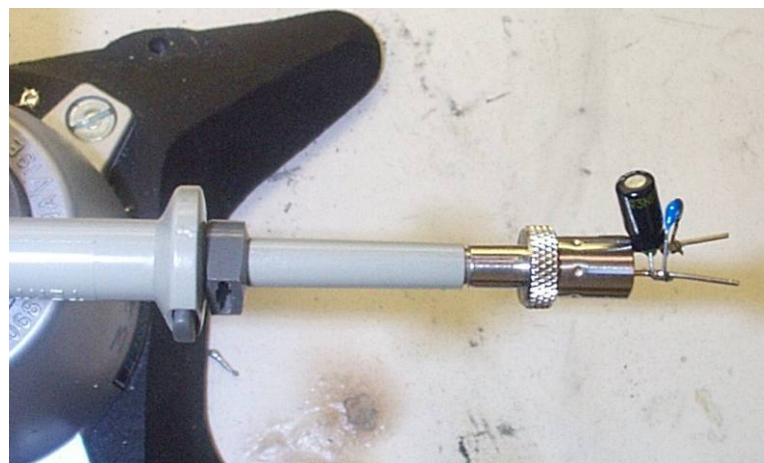
#### 13.11.1 Ripple Measurement Technique

For DC output ripple measurements, a modified oscilloscope test probe must be utilized in order to reduce spurious signals due to pickup. Details of the probe modification are provided in the figures below.

The 5125BA probe adapter is affixed with two capacitors tied in parallel across the probe tip. The capacitors include one (1) 0.1  $\mu\text{F}$  / 50 V ceramic type and one (1) 1.0  $\mu\text{F}$ /50V aluminum electrolytic. ***The aluminum electrolytic type capacitor is polarized, so proper polarity across DC outputs must be maintained (see below).***

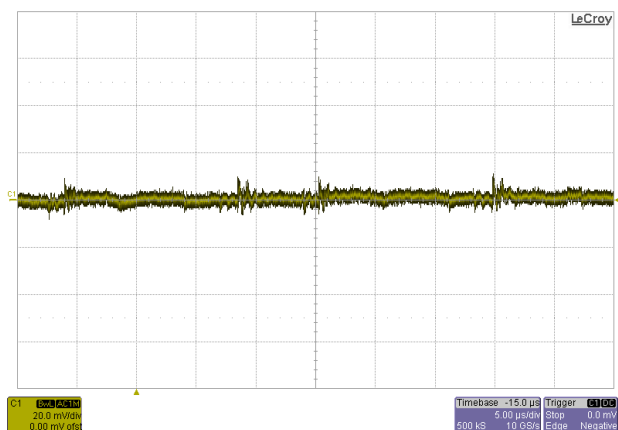


**Figure 42** – Oscilloscope Probe Prepared for Ripple Measurement.  
(End Cap and Ground Lead Removed)

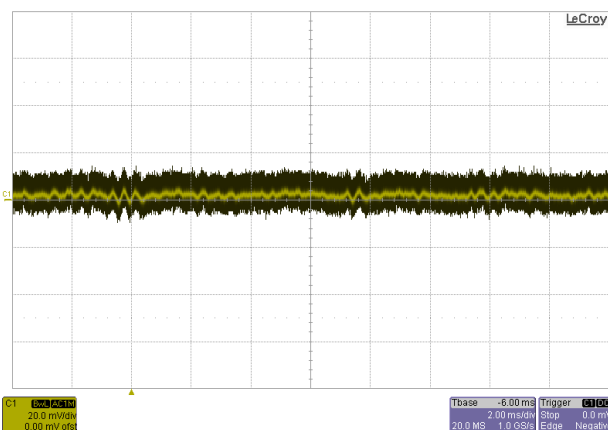


**Figure 43** – Oscilloscope Probe with Probe Master 5125BA BNC Adapter.  
(Modified for ripple measurement, and two parallel decoupling capacitors added)

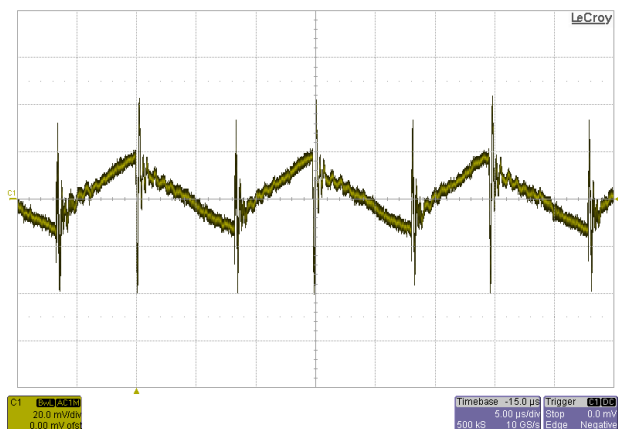
## 13.11.2 Measurement Results



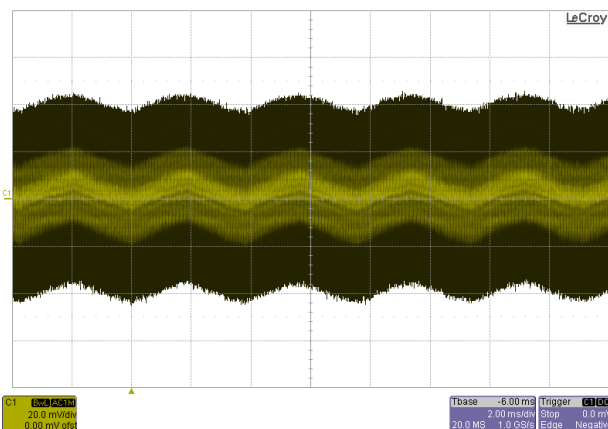
**Figure 44** – Standby Output Ripple: 380 VDC  
 $V_{STBY}$ , 20 mV / div., 5  $\mu$ s / div. (Full Load)



**Figure 45** – Standby Output Ripple: 380 VDC.  
 $V_{STBY}$ , 20 mV / div., 2 ms / div. (Full Load)



**Figure 46** – Main Output Ripple: 380 VDC  
 $V_{MAIN}$ , 20 mV / div., 5  $\mu$ s / div. (Full Load)

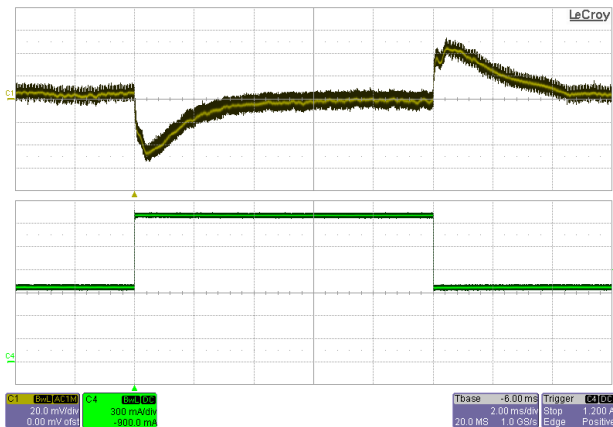


**Figure 47** – Main Output Ripple: 380 VDC  
 $V_{MAIN}$ , 20 mV / div., 2 ms / div. (Full Load)

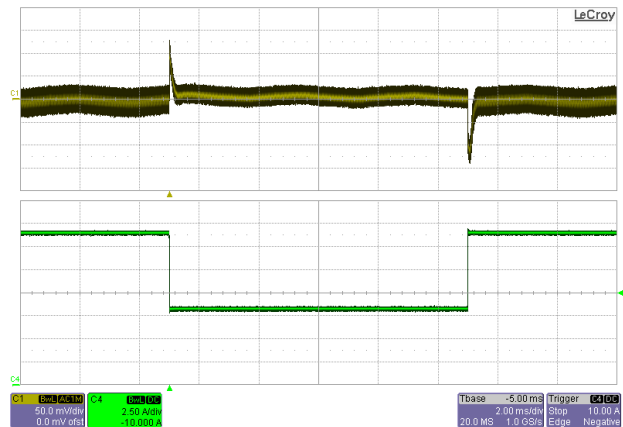


### 13.12 Main and Standby Load Transient Response

The waveform shows the instantaneous output voltage for 33% to 66% step load change. The voltage step change is under 50 mV for Standby output and under 150 mV for Main output. For the Standby test the Main output was off, for the Main test the Standby output was loaded at 50%.



**Figure 48** – Standby Step Load: 380 VDC  
Upper:  $V_{STBY}$ , 20 mV / div.  
Lower: Standby  $I_{OUT}$ , 300 mA, 2ms / div.



**Figure 49** – Main Step Load: 380 VDC  
Upper:  $V_{MAIN}$ , 50 mV / div.  
Lower: Main  $I_{OUT}$ , 2.5 A, 2 ms / div.

**14 Design Notes:**

1. Pay extra attention when mounting the TFS762HG and the eSIP clip. TFS762HG must be placed flush with the PCB, as close as possible. There must be at least 2 mm clearance between clip and TFS762HG edge to avoid short-circuit from exposed metallic ends to mounting clip.
2. For convenience, two LED footprints are provided for optional visual control. All no-load tests must be completed without LEDs.
3. J1\_OPTIO is provided at schematic and BOM level as an alternative option only.



**15 Revision History**

| Date      | Author | Revision | Description and changes   | Reviewed    |
|-----------|--------|----------|---------------------------|-------------|
| 09-Nov-10 | AN     | 1.0      | Initial Release           | Apps & Mktg |
| 16-Nov-11 | KM     | 1.1      | Updated BOM and Schematic |             |
|           |        |          |                           |             |
|           |        |          |                           |             |



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